

VT82C580VPX

APOLLO VPX

Low-Cost Pentium / PCI North Bridge with 66/75MHz CPU Support and SDRAM / EDO / FPG Interface for Green PC Desktop Computers

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REVISION HISTORY

Document Release	Date	Revision	Initials
Preliminary	1/2/97	Original release based on VT82C595 Apollo VP2 data sheet revision 0.4	DH
		(VPX register set is more like Apollo VP2 than like VT82C580 Apollo VP)	
		Changed intro and features list to reflect Apollo VPX	
		Added pinouts, electrical, and mechanical specs from 580VP data sheet	
		Added tables of pins in alphabetical order for both chips	
		Changed pinouts to reflect VPX	
		- Removed UMA (added CPURSTI and CPURSTO on MREQ0/1#)	
		- Added 64Mb DRAM support (added MA12/13 opt on MBEN/RAS5)	
		 Improved SDRAM support (added SWEC#/SCASC# on WE/Mgnt) 	
		Changed registers to reflect VPX	
		- Removed ECC registers (no pins for ECC in PQFP package)	
		- Added Rx50[2], Rx65[2], Rx66[5], Rx68[3], Rx6B[2]	
		- Swapped bytes of Rx54-55 & 56-57 to match silicon (same in VP2)	



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VIA VT82C580 APOLLO VPX

LOW-COST PENTIUM / PCI NORTH BRIDGE WITH 66/75MHZ CPU SUPPORT AND SDRAM / EDO / FPG INTERFACE FOR GREEN PC DESKTOP COMPUTERS

• Flexible CPU Interface

- Supports 64-bit Pentium[™], AMD 5_K86[™], AMD 6_K86[™] and Cyrix 6_X86[™] CPUs
- CPU external bus speed up to 75 MHz (asynchronous) or 66MHz (synchronous) (internal 200Mhz and above)
- Supports CPU internal write-back cache
- System management interrupt, memory remap and STPCLK mechanism
- Cyrix 6_x86 linear burst support
- CPU NA# / Address pipeline capability

Low Cost

- PQFP packaging for low-cost implementation of 64-bit Pentium-CPU, 64-bit system memory, and 32-bit PCI
- VT82C580 Apollo VPX Chipset: VT82C585VPX system controller and VT82C587VP Data Buffers
- VT82C586B includes UltraDMA-33 EIDE, USB, and Keyboard / Mouse Interfaces plus RTC / CMOS
- Six TTLs for a complete main board implementation

PCI/ISA Green PC Ready

- Supports 3.3V or 5V interface to CPU, system memory, and / or PCI bus
- Supports CPUs with internal voltages below 3.3V
- PC-97 compatible using VT82C586B South Bridge with ACPI Power Management

• Advanced Cache Controller

- Direct map write back or write through secondary cache
- Pipelined burst synchronous SRAM (PBSRAM) cache support
- Flexible cache size: 0K/256K/512K/1M/2MB
- 32 byte line size to match the primary cache
- Integrated 10-bit tag comparator
- 3-1-1-1 read/write timing for PBSRAM access at 66/75 MHz
- 3-1-1-1-1-1 back to back read timing for PBSRAM access at 66/75 MHz
- Sustained 3 cycle write access for PBSRAM access or CPU to DRAM and PCI bus post write buffers at 66/75 MHz
- Data streaming for simultaneous primary and secondary cache line fill
- System and video BIOS cacheable and write-protect
- Programmable cacheable region and cache timing



• Fast DRAM Controller

- Fast Page Mode/EDO/Synchronous-DRAM support in a mixed combination
- Mixed 1M/2M/4M/8M/16MxN DRAMs
- 6 banks up to 512MB DRAMs
- Flexible row and column addresses
- 64-bit or 32-bit data width in arbitrary mixed combination
- 3.3v and 5v DRAM without external buffers
- Two-bank interleaving for 16Mbit SDRAM support
- Two-bank and four bank interleaving for 64Mbit SDRAM support (14 MA lines)
- Four cache lines (16 quadwords) of CPU/cache to DRAM write buffers
- Concurrent DRAM writeback
- Speculative DRAM access
- Read around write capability for non-stalled CPU read
- Burst read and write operation
- 4-2-2-2 on page, 7-2-2-2 start page and 9-2-2-2 off page timing for EDO DRAMs at 50/60 MHz
- 5-2-2-2 on page, 8-2-2-2 start page and 11-2-2-2 off page timing for EDO DRAMs at 66 MHz
- 6-1-1-1 on page, 8-1-1-1 start page and 10-1-1-1 off page for SDRAMs at 66 MHz
- 5-2-2-3-1-2-2 back-to-back access for EDO DRAM at 66 MHz
- 6-1-1-3-1-1-1 back-to-back access for SDRAM at 66 MHz
- BIOS shadow at 16KB increment
- Decoupled and burst DRAM refresh with staggered RAS timing
- Programmable refresh rate, CAS-before-RAS refresh and refresh on populated banks only

• Intelligent PCI Bus Controller

- 32 bit 3.3/5v PCI interface
- Synchronous divide-by-two and asynchronous PCI bus interface
- PCI master snoop ahead and snoop filtering
- PCI master peer concurrency
- Synchronous bus to CPU clock with divide-by-two from the CPU clock
- Automatic detection of data streaming burst cycles from CPU to the PCI bus
- Five levels (double-words) of CPU to PCI posted write buffers
- Byte merging in the write buffers to reduce the number of PCI cycles and to create further PCI bursting possibilities
- Zero wait state PCI master and slave burst transfer rate
- PCI to system memory data streaming up to 132Mbyte/sec
- Forty-eight levels (double-words) of post write buffers from PCI masters to DRAM
- Sixteen levels (double-words) of prefetch buffers from DRAM for access by PCI masters
- Enhanced PCI command optimization (MRL, MRM, MWI, etc.)
- Complete steerable PCI interrupts
- Supports L1 write-back forward to PCI master read to minimize PCI read latency
- Supports L1 write-back merged with PCI master post-write to minimize DRAM utilization
- Provides transaction timer to fairly arbitrate between PCI masters
- PCI-2.1 compliant
- Built-in nand-tree pin scan test capability
- 0.6um mixed voltage, high speed / low power CMOS process
- VT82C585VPX: 208-pin PQFP Package
- VT82C587VP: 100-pin PQFP Package

OVERVIEW

The VT82C580VPX *Apollo-VPX* is a high performance, cost-effective and energy efficient chip set for implementation of PCI / ISA desktop and notebook personal computer systems based on 64-bit P54C/Pentium/K5/K6/M1 super-scalar processors. The CPU / cache connection is supported using an "asynchronous" interface up to 75Mhz CPU external bus speed (with CPU internal speed up to 200Mhz and above), with CPUs such as the "P200+" processors from Cyrix / IBM Microelectronics. The "asynchronous" interface allows the processor external bus frequency to be increased above 66MHz while still allowing the PCI bus to run at the specified top frequency of 33MHz. The chipset also supports CPU external bus speeds up to 66MHz in "synchronous" mode, so may also be used in boards designed around the popular VT82C580VP (Apollo VP) chipset. The 66MHz external bus speed is used primarily for Intel and AMD processors. The CPU, DRAM and PCI bus are all independently powered so that each of the bus can be run at 3.3v or 5v, independently. The ISA bus always runs at 5v.

The VT82C580VPX chip set consists of the VT82C585VPX system controller, the VT82C586B PCI to ISA bridge, and two instances of the VT82C587VP data buffers. The VT82C585VPX is the only different component in a VPX-based system from the chips used in an Apollo VP system: the same VT82C586B South Bridge chip may be used with all VIA North Bridge chips (Pentium and PentiumPro-based designs) and the VT82C587VP Data Buffer is the same chip as is used in Apollo VP designs.

The CPU bus is minimally loaded with only the CPU, secondary cache and the chip set. The VT82C587VP data buffers isolate the CPU bus from the DRAM and PCI bus so that CPU and cache operation may run reliably at the high frequencies demanded by today's processors. The VT82C585VPX contains multiple deep FIFOs to allow efficient concurrent operation and DRAM utilization. The VT82C586B PCI to ISA bridge includes integrated 206-style IPC (DMA, interrupt controller and timer), integrated keyboard controller with PS2 mouse support, integrated DS12885 style real time clock with extended 256 byte CMOS RAM, ACPI-compatible Power Management subsystem, integrated master mode enhanced IDE / UltraDMA-33 disk controller with full scatter and gather capability, and integrated USB (universal serial bus) interface with root hub and two function ports with built-in physical layer transceivers (refer to the separate VT82C586B Data Sheet for additional information). A complete main board can be implemented with only six TTLs. Refer to Figure 1 for the system block diagram.

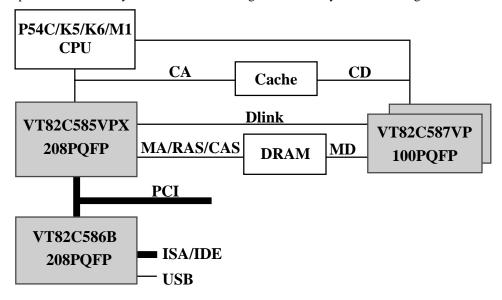


Figure 1. Apollo VPX System Block Diagram

The secondary (L2) cache is based on Burst Synchronous (Pipelined or non-pipelined) SRAM cache modules from 128KB to 2MB. For burst synchronous SRAMs, 3-1-1-1 timing can be achieved for both read and write transactions at 66Mhz. Four cache lines (16 quadwords) of CPU / cache to DRAM write buffers with concurrent write-back capability are included in the VT82C587VP data buffer chips to speed up cache read and write miss cycles.

The VT82C580VPX supports six banks of DRAMs up to 512KB. The DRAM controller supports Standard Page Mode DRAM, EDO-DRAM, and Synchronous DRAM in a flexible mixed/match manner. Synchronous DRAM allows zero wait state bursting between the DRAM and the VT82C587VP data buffers at 66/75Mhz. The six banks of DRAM are grouped into three pairs with



an arbitrary mixture of 256K/512K/1M/2M/4M/8M/16MxN DRAMs. Each bank may be populated with either 32bit or 64bit data width.

The VT82C580VPX supports the shadowing of the system, video and other BIOS to speed up access. The video and system BIOS can also be write-protected and made cacheable. Access cycles to either E , D or C segment can be programmed to be an on-board EPROM cycle to allow the combination of system and video BIOS for an all-in-one system board implementation. The VT82C580VPX can also be programmed to recognize write cycles as EPROM cycles to support field upgradability of flash EPROM BIOS.

The VT82C580VPX supports a 3.3/5v 32-bit PCI bus with 64-bit to 32-bit data conversion. Five levels (doublewords) of post write buffers are included to allow for concurrent CPU and PCI operation. Consecutive CPU addresses are converted into burst PCI cycles with byte merging capability for optimal CPU to PCI throughput. A 16-bit fast data link is established between the two VT82C587VP data units and the VT82C585VPX system controller so that the address, data and command information for CPU to PCI bus transactions is contained in the same chip. This arrangement, unique to the VT82C580VP and VT82C580VPX chipsets is crucial in achieving zero wait state buffer movement and implementing sophisticated and upgradable buffer management schemes such as the byte merging. For PCI master operation, forty-eight levels (doublewords) of post write buffers and sixteen levels (doublewords) of prefetch buffers are included for concurrent PCI bus and DRAM/cache accesses. The chipset also supports enhanced PCI bus commands such as Memory-Read-Line, Memory-Read-Multiple and Memory-Write-Invalid commands to minimize snoop overhead. In addition, the chipset supports advanced features such as snoop ahead, snoop filtering, L1 write-back forward to PCI master and L1 write-back merged with PCI post write buffers to minimize PCI master read latency and DRAM utilization. The VT82C586B PCI to ISA bridge supports four levels (doublewords) of line buffers, type F DMA transfers and delayed transactions to allow efficient PCI bus utilization and is PCI-2.1 compliant.

The integrated master mode IDE controller of the VT82C586B supports a dual-channel / four-device enhanced IDE bus with enhancements for UltraDMA-33 operation and has sixteen levels of double-word prefetch and write buffers. The data bus, control signals, write buffers and prefetch buffers are separated from those of the PCI bus so that performance and electrical loading are optimized. The command and recovery time of each IDE device can be individually programmed in units of PCI bus clocks to achieve optimal speed of the device up to 33MB/s. Other features of the IDE controller include interlaced dual channel commands, full scatter and gather capability, bus master programming interface for ATA controllers, SFF-8038 compliance and complete software driver support. The VT82C586B South Bridge also includes an integrated RTC with extended 256-byte CMOS, integrated keyboard controller, integrated USB (Universal Serial Bus) controller, and a sophisticated power management unit that is compliant with both APM 1.1 and ACPI 0.9 to allow design of PC systems that are fully PC-97 compliant.

The VT82C580VPX is ideal for high performance, high quality, high energy efficient and high integration desktop and notebook PCI/ISA computer systems.



PINOUTS

VT82C585VPX Pinouts

Figure 2. VT82C585VPX Pin Diagram (Top View)

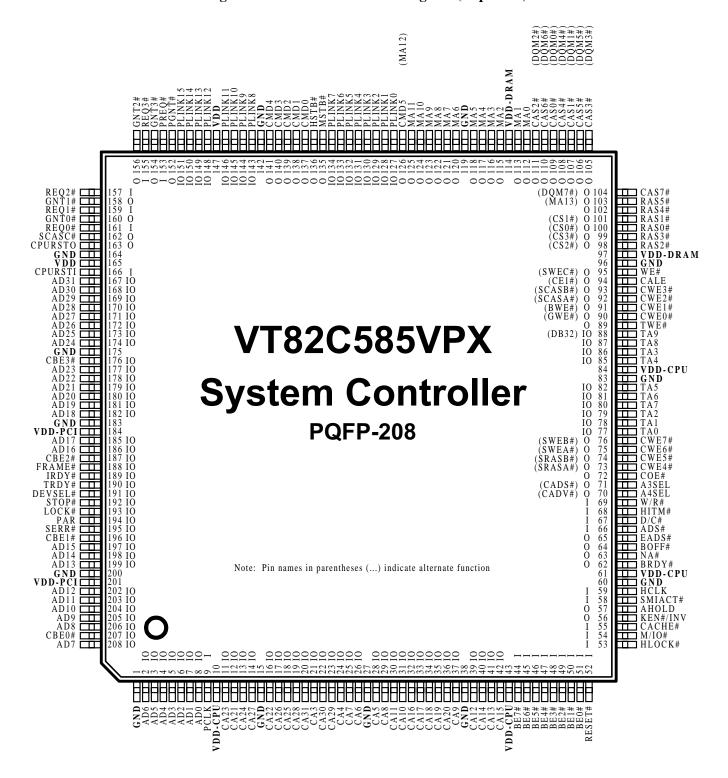




Figure 3. VT82C585VPX Pin List (Alphabetical Order)

Pin No	Pin Name	Pin No	Pin Name	Pin No	Pin Name	Pin No	Pin Name
71	A3SEL / CADS#	42	CA15	107	DQM1# / CAS1#	132	PLINK5
70	A4SEL / CADV#	32	CA16	111	DQM2# / CAS2#	133	PLINK6
8	AD0	33	CA17	105	DQM3# / CAS3#	134	PLINK7
7	AD1	34	CA18	108	DQM4# / CAS4#	143	PLINK8
6	AD2	35	CA19	106	DQM5# / CAS5#	144	PLINK9
5	AD3	36	CA20	110	DQM6# / CAS6#	145	PLINK10
4	AD4	12	CA21	104	DQM7# / CAS7#	146	PLINK11
3	AD5	16	CA22	65	EADS#	148	PLINK12
2	AD6	11	CA23	188	FRAME#	149	PLINK13
208	AD7	13	CA24	1	GND	150	PLINK14
206	AD8	18	CA25	15	GND	151	PLINK15
205	AD9	17	CA26	27	GND	153	PREQ#
204	AD10	14	CA27	38	GND	100	RAS0# / CS0#
203	AD11	19	CA28	60	GND	101	RAS1# / CS1#
202	AD12	23	CA29	83	GND	98	RAS2# / CS2#
199	AD13	22	CA30	96	GND	99	RAS3# / CS3#
198	AD14	20	CA31	119	GND	102	RAS4#
197	AD15	55	CACHE#	142	GND	103	RAS5# / MA13
186	AD16	71	CADS# / A3SEL	164	GND	161	REQ0#
185	AD17	70	CADV# / A4SEL	175	GND	159	REQ1#
182	AD18	94	CALE / CE1#	183	GND	157	REQ2#
181	AD19	109	CAS0# / DQM0#	200	GND	155	REQ3#
180	AD20	107	CAS1# / DQM1#	160	GNT0#	52	RESET#
179	AD21	111	CAS2# / DQM2#	158	GNT1#	92	SCASA# / CWE2#
178	AD22	105	CAS3# / DQM3#	156	GNT2#	93	SCASB# / CWE3#
177	AD23	108	CAS4# / DQM4#	154	GNT3#	162	SCASC#
174	AD24	106	CAS5# / DQM5#	90	GWE# / CWE0#	195	SERR#
173	AD25	110	CAS6# / DQM6#	59	HCLK	58	SMIACT#
172	AD26	104	CAS7# / DQM7#	68	HITM#	73	SRASA# / CWE4#
171	AD27	207	CBE0#	53	HLOCK#	74	SRASB# / CWE5#
170	AD28	196	CBE1#	136	HSTB#	192	STOP#
169	AD29	187	CBE2#	189	IRDY#	75	SWEA# / CWE6#
168	AD30	176	CBE3#	56	KEN#/INV	76	SWEB# / CWE7#
167	AD31	94	CE1# / CALE	193	LOCK#	95	SWEC# / WE#
66	ADS#	137	CMD0	54	M/IO#	77	TA0
57	AHOLD	138	CMD1	112	MA0	78	TA1
51	BE0#	139	CMD2	113	MA1	79	TA2
50	BE1#	140	CMD3	115	MA2	86	TA3
49	BE2#	141	CMD4	116	MA3	85	TA4
48	BE3#	126	CMD5 / MA12	117	MA4	82	TA5
47	BE4#	72	COE#	118	MA5	81	TA6
46	BE5#	166	CPURSTI	120	MA6	80	TA7
45	BE6#	163	CPURSTO	121	MA7	87	TA8
44	BE7#	100	CS0# / RAS0#	122	MA8	88	TA9 / DB32
64	BOFF#	101	CS1# / RAS1#	123	MA9	190	TRDY#
62	BRDY#	98	CS2# / RAS2#	124	MA10	89	TWE#
91	BWE# / CWE1#	99	CS3# / RAS3#	125	MA11	147	VDD
21	CA3	90	CWE0# / GWE#	126	MA12 / CMD5	165	VDD
24	CA4	91	CWE1# / BWE#	103	MA13 / RAS5#	10	VDD-CPU
28	CA5	92	CWE2# / SCASA#	135	MSTB#	43	VDD-CPU
26	CA6	93	CWE3# / SCASB#	63	NA#	61	VDD-CPU
25	CA7	73	CWE4# / SRASA#	194	PAR	84	VDD-CPU
29	CA8	74	CWE5# / SRASB#	9	PCLK	97	VDD-DRAM
37	CA9	75	CWE6# / SWEA#	152	PGNT#	114	VDD-DRAM
31	CA10	76	CWE7# / SWEB#	127	PLINK0	184	VDD-PCI
30	CA11	67	D/C#	128	PLINK1	201	VDD-PCI
39	CA12	88	DB32 / TA9	129	PLINK2	69	W/R#
41	CA13	191	DEVSEL#	130	PLINK3	95	WE# / SWEC#
40	CA14	109	DQM0# / CAS0#	131	PLINK4		



Table 1. VT82C585VPX Pin Descriptions

Signal Name	Pin No.	Power	I/O	Signal Description		
Clock Control						
HCLK	59	CPU	I	Host Clock. This pin receives a buffered host clock which is used by all VT82C585VPX logic in the Host CPU clock domain. This pin should connect to the same clock net that is used to clock the CPU.		
PCLK	9	CPU	I	PCI Clock. Used by all logic in the PCI clock domain. Typically host clock divided by two for 66MHz CPU operation but is not required to be synchronous with HCLK. Maximum 33MHz to meet PCI specifications.		

	Reset Control							
RESET#	52	PCI	I	Reset. Resets the chip and sets all register bits to their default values.				
CPURSTI	166	PCI	I	CPU Reset In. Used to synchronize the CPURST signal from the south				
				bridge chip to the CPU (required for 75MHz operation, optional for 66).				
CPURSTI	162	CPU	O	CPU Reset Out. Synchronized CPURST signal to the CPU.				

	CPU Interface							
ADS#	66	CPU	I	Address Strobe. The CPU asserts ADS# in T1 of the CPU bus cycle.				
M/IO#	54	CPU	I	Memory / IO				
W/R#	69	CPU	I	Write / Read				
D/C#	67	CPU	I	Data / Control				
BE#[7:0]	44-51	CPU	I	Byte Enables. Indicate byte lanes accessed in the current CPU cycle.				
CA[31:3]	20, 22-23, 19, 14, 17-18, 13, 11, 16, 12, 36- 32, 42, 40-41, 39, 30-31, 37, 29, 25-26, 28, 24, 21	CPU	В	Address Bus. CA[31:3] connect to the address bus of the CPU. During CPU cycles CA[31:3] are inputs. These signals are driven by the VT82C585VPX during cache snooping operations.				
BRDY#	62	CPU	О	Bus Ready. The VT82C585VPX asserts BDRY# to indicate to the CPU that data is available on reads or has been received on writes.				
EADS#	65	CPU	О	External Address Strobe. Asserted by the VT82C585VPX to inquire the L1 cache when serving PCI master accesses to main memory.				
KEN#/INV	56	CPU	О	Cache Enable / Invalidate. KEN#/INV functions as both the KEN# signal during CPU read cycles and INV during L1 cache snoop cycles.				
HITM#	68	CPU	I	Hit Modified. Asserted by the CPU to indicate that the address presented with the last assertion of EADS# is modified in the L1 cache and needs to be written back.				
HLOCK#	53	CPU	I	Host Lock. All CPU cycles sampled with the assertion of HLOCK# and ADS# until the negation of HLOCK# must be atomic.				
CACHE#	55	CPU	I	Cacheable. Asserted by the CPU during a read cycle to indicate the CPU can perform a burst line fill. Asserted by the CPU during a write cycle to indicate that the CPU will perform a burst write-back cycle.				
AHOLD	57	CPU	О	Address Hold. AHOLD is asserted while PCI masters are accessing main memory. AHOLD is held for the duration of PCI burst transfers.				
NA#	63	CPU	О	Next Address				
BOFF#	64	CPU	О	Back Off. Asserted by the VT82C585VPX when required to terminate a CPU cycle that was in progress.				
SMIACT#	58	CPU	I	System Management Interrupt Active. This is asserted by the CPU when it is in system management mode as a result of an SMI.				



	Cache Control							
COE#	72	CPU	О	Cache SRAM Output Enable				
CWE#[7:0] /	76-73,	CPU	О	Multifunction Pins:				
SWE#A-B,	93-90			Global write option off (Rx50[2] = 0): Cache SRAM Write Enables for				
SRAS#A-B,				each byte.				
SCAS#A-B,				Global write option on (Rx50[2] = 1): Synchronous DRAM Command				
BWE#, GWE#				indicators and BWE#/GWE# for global write SRAM control.				
TWE#	89	CPU	О	Tag Write Enable. When asserted, new state and tag addresses are				
				written into the external tag.				
A3SEL / CADS#	71	CPU	О	Multifunction Pin:				
				Async SRAM: Cache Address 3. A3SEL is used to sequence through the				
				Quad-words in a cache line during a burst operation.				
				Sync SRAM: Cache Address Strobe. Assertion causes the burst SRAM				
				to load the BSRAM address register from BSRAM address pin.				
A4SEL / CADV#	70	CPU	О	Multifunction Pin:				
				Async SRAM: Cache Address 4. A4SEL is used to sequence through the				
				Quad-words in a cache line during a burst operation.				
				Sync SRAM: Cache Advance. Assertion causes the burst SRAM to				
TA [0] / DD22	00 07 00 01	CPU	В	advance to the next Quad-word in the cache line.				
TA[9] / DB32	88, 87, 80, 81,	CPU	В	Tag Address. These are inputs during CPU accesses, outputs during L2 cache line fills, and L2 line invalidates during inquire cycles. TA9 is a				
TA[8:0]	82, 85, 86, 79- 77			multi-function pin and will act as DB32 to the VT82C587VP chips when				
	/ /			32-bit DRAM mode is enabled.				
CALE / CE1#	94	CPU	0	Multifunction Pin:				
CALE / CEI#	2 4	CrU		Async SRAM: Cache Address Latch. CALE is used to control the cache				
				address latches.				
				Sync SRAM: Chip Enable 1. CE1# is used as chip-select 1 for BSRAM.				



	DRAM Control							
MA[11:0]	125-120, 118- 115, 113-112	DRAM	О	Memory Address. DRAM address lines 0-11.				
MA12 / CMD5	126	DRAM	0	Dual Function Pin: Command 5. This function is provided for backwards compatibility: In VT82C585VP-based designs (i.e., non-VPX), this pin (previously called "MBEN#) was connected to the VT82C587VP "CMD5" pin for UMA control. For compatibility with those systems, this pin may be programmed to remain high at all times. In new or modified designs, the VT82C587VP CMD5 input may be tied high so that this pin may be used to drive Memory Address 12 for support of larger memory sizes.				
RAS5#/MA13	103	DRAM	0	FPG/EDO/BEDO DRAM: Row Address Strobe for bank 5 or Memory Address 13. Synchronous DRAM: Memory Address 13				
RAS4#	102	DRAM	О	FPG/EDO/BEDO DRAM: Row Address Strobe for bank 4 Synchronous DRAM: Unused				
RAS[3:0]# / CS[3:0]#	99-98, 101-100	DRAM		FPG/EDO/BEDO DRAM: Row Address Strobe for each bank. Synchronous DRAM: Chip Select for each bank.				
CAS[7:0]# / DQM[7:0]#	104, 110, 106, 108, 105, 111, 107, 109	DRAM	0	FPG/EDO/BEDO DRAM: Column Address Strobe for each byte lane. Synchronous DRAM: Data Mask for each byte lane.				
SRASA#, SRASB#	73, 74	DRAM	O	FPG/EDO/BEDO DRAM: Inactive. Synchronous DRAM: Row Address Command Indicators (three identical copies for better drive).				
SCASA#, SCASB#, SCASC#	92, 93	DRAM	0	FPG/EDO/BEDO DRAM: Inactive. Synchronous DRAM: Column Address Command Indicators (three identical copies for better drive).				
SWEA#, SWEB#, SWEC# / WE#	75, 76, 95	DRAM	О	FPG/EDO/BEDO DRAM: Write Enable (pin 95). Pins 75-76 inactive. Synchronous DRAM: Write Enable Command Indicators (three identical copies for better drive).				

	VT82C587VP Interface							
PLINK[15:0]	151-148, 146- 143, 134-127	DRAM	В	PCI Link. This is the data path between CPU / main memory and the PCI bus. PCI main memory reads and CPU-to-PCI writes are driven onto these pins by the VT82C587VP. CPU reads from PCI and PCI writes to main memory are received on this bus by the VT82C587VP. Each VT82C587VP is connected to one byte of this bus.				
MSTB#	135	DRAM	О	Memory Strobe. Assertion causes data to be posted in the DRAM Write Buffer.				
HSTB#	136	DRAM	О	Host Strobe. Assertion causes data to be posted in the CPU Read Buffer.				
CMD[4:0]	141-137	DRAM	0	Command. The VT82C585VPX uses these signals to control the buffers in the VT82C587VP chips. See also pin 126 above for CMD5 function.				

Table 2. VT82C585<u>VP</u> vs. VT82C585<u>VPX</u> Pinout Differences Summary

Pin #	VT82C585VP	VT82C585VPX
95	WE#	WE# / SWEC#
103	RAS5#	RAS5# / MA13
126	MBEN#	CMD5 / MA12
162	MGNT#	SCASC#
163	MREQ0#	CPURSTO
166	MREQ1#	CPURSTI



	PCI Bus Interface					
FRAME#	188	PCI	В	Frame. Assertion indicates the address phase of a PCI transfer. Negation indicates that one more data transfer is desired by the cycle initiator.		
AD[31:0]	167-174, 177- 182, 185, 186, 197-199, 202- 206, 208, 2-8	PCI	В	Address / Data Bus. The standard PCI address and data lines. The address is driven with FRAME# assertion and data is driven or received in following cycles.		
C/BE#[3:0]	176, 187, 196, 207	PCI	В	Command / Byte Enable. Commands are driven with FRAME# assertion. Byte enables corresponding to supplied or requested data are driven on following clocks.		
IRDY#	189	PCI	В	Initiator Ready. Asserted when the initiator is ready for data transfer.		
TRDY#	190	PCI	В	Target Ready. Asserted when the target is ready for data transfer.		
STOP#	192	PCI	В	Stop. Asserted by the target to request the master to stop the current transaction.		
DEVSEL#	191	PCI	В	Device Select. This signal is driven by the VT82C585VPX when a PCI initiator is attempting to access main memory. It is an input when the VT82C585VPX is acting as a PCI initiator.		
PAR	194	PCI	В	Parity. A single parity bit is provided over AD[31:0] and C/BE[3:0].		
SERR#	195	PCI	В	System Error. The VT82C585VPX will pulse this signal when it detects a system error condition.		
LOCK#	193	PCI	В	Lock. Used to establish, maintain, and release resource lock on the PCI bus		
PREQ#	153	PCI	I	PCI Request. This signal comes from the south bridge chip (VT82C586, 586A, or 586B). PREQ# is the south bridge chip's request for the PCI bus.		
PGNT#	152	PCI	О	PCI Grant. This signal driven by the VT82C585VPX to grant PCI access to the VT82C586, 586A, or 586B south bridge.		
REQ#[3:0]	155, 157, 159, 161	PCI	I	Request. PCI master requests for the PCI bus.		
GNT#[3:0]	154, 156, 158, 160	PCI	О	Grant. Permission is given to the master to use the PCI bus.		

Power and Ground				
VDD 147, 165 5V I Power Supply for the internal logic of the VT82C585VPX chip (5v)				
VDD-CPU	VDD-CPU 10, 43, 61, 84 CPU I Power Supply for the CPU Bus (3.3v or 5v)		Power Supply for the CPU Bus (3.3v or 5v)	
VDD-PCI 184, 201 PCI I Power Supply for the PCI Bus (3.3v or 5v)				
VDD-DRAM	97, 114	DRAM	I	Power Supply for the DRAM Bus (3.3v or 5v)
GND	1, 15, 27, 38,	0V	I	Ground
	60, 83, 96, 119,			
	142, 164, 175,			
	183, 200			

VT82C587VP Pinouts

| CAS# | STATE | STATE

Figure 4. VT82C587VP Pin Diagram (Top View)



Figure 5. VT82C587VP Pin List (Alphabetical Order)

Pin No.	Pin Name						
83	CAS#	94	HD06	24	HD31	76	MD23
29	CMD0	95	HD07	38	HSTB#	42	MD24
28	CMD1	96	HD08	45	MD00	46	MD25
27	CMD2	97	HD09	49	MD01	51	MD26
26	CMD3	98	HD10	55	MD02	56	MD27
25	CMD4	99	HD11	60	MD03	61	MD28
79	CMD5	2	HD12	64	MD04	69	MD29
85	DB32	3	HD13	68	MD05	74	MD30
1	GND	4	HD14	73	MD06	78	MD31
10	GND	5	HD15	77	MD07	39	MSTB#
15	GND	6	HD16	43	MD08	37	PLINK0
40	GND	7	HD17	47	MD09	36	PLINK1
50	GND	8	HD18	52	MD10	35	PLINK2
59	GND	9	HD19	57	MD11	34	PLINK3
66	GND	11	HD20	62	MD12	33	PLINK4
70	GND	12	HD21	71	MD13	32	PLINK5
82	GND	13	HD22	75	MD14	31	PLINK6
90	GND	14	HD23	80	MD15	30	PLINK7
81	HCLK	17	HD24	44	MD16	84	RESET#
86	HD00	18	HD25	48	MD17	41	VDD
87	HD01	19	HD26	54	MD18	16	VDD-CPU
88	HD02	20	HD27	58	MD19	91	VDD-CPU
89	HD03	21	HD28	63	MD20	100	VDD-CPU
92	HD04	22	HD29	65	MD21	53	VDD-DRAM
93	HD05	23	HD30	72	MD22	67	VDD-DRAM



Table 3. VT82C587VP Pin Descriptions

Signal Name	Pin No.	Power	I/O	Signal Description	
CPU Data Port					
HD[31:0]	24-17, 14-11,	CPU	В	Host CPU Data . These signals are connected to the CPU data bus. The	
	9-2, 99-92, 89- CPU data bus is interleaved between the two VT82C587VP chips for				
	86			every byte, effectively creating an even and odd 587VP.	

DRAM Data Port						
MD[31:0]	78, 74, 69, 61,	DRAM	В	Memory Data. These signals are connected to the DRAM data bus. The		
	56, 51, 46, 42,			DRAM data bus is interleaved between the two VT82C587VP for every		
	76, 72, 65, 63,			byte, effectively creating an even and odd VT82C587VP.		
	58, 54, 48, 44,					
	80, 75, 71, 62,					
	57, 52, 47, 43,					
	77, 73, 68, 64,					
	60, 55, 49, 45					

	VT82C585VPX Interface					
DB32	85	DRAM	I	DRAM Width . This is used to control the width of the DRAM data bus		
CMD[5:0]	79, 25-29	DRAM	Ι	I Command. The buffers in the VT82C587VP are controlled by the VT82C585VPX through these command signals. The CMD5 input is used for UMA support only so may be tied high. The VT82C585VPX may be programmed to drive its CMD5 output high at all times for backwards compatibility with 82C585VP-based (non-VPX) designs.		
HSTB#	38	DRAM	I	Host Data Strobe . Assertion causes data to be posted in the CPU read buffer		
MSTB#	39	DRAM	I	Memory Strobe . Assertion causes data to be posted in the DRAM write buffer.		
PLINK[7:0]	30-37	DRAM	В	PCI Link. These signals are connected to the PLINK data bus on the VT82C585VPX. This the data path between the VT82C585VPX and the VT82C587VP chips. Each VT82C587VP connects to one-byte of the 16-bit bus.		

Clock and Miscellaneous Control				
HCLK 81 CPU I Host Clock . Primary clock input used to drive the part.		Host Clock . Primary clock input used to drive the part.		
RESET# 84 CPU I Host Reset . Primary reset signal for the VT82C587VP.				
CAS#	83	CPU	I	DRAM CAS Synchronization. Connects to any DRAM CAS signal to synchronize the clocks with DRAM CAS. Required for Burst EDO DRAM operation only; can be tied high if BEDO DRAMs will never be used in the system design. It is recommended to maintain same skew among the eight DRAM CAS# lines for Burst EDO operation.

	Power and Ground				
VDD 41 5V I Power Supply for the Internal Logic of the chip (5v)					
VDD-DRAM	53, 67	DRAM	I	Power Supply for the DRAM interface (3.3v or 5v)	
VDD-CPU	16, 91, 100	91, 100 CPU I Power Supply for the CPU bus (3.3v or 5v).			
GND	1, 10, 15, 40,	0V	I	Ground	
	50, 59, 66, 70,				
	79, 90				



REGISTERS

Register Overview

The following tables summarize the configuration and I/O registers of the VT82C585VPX. These tables also document the power-on default value ("Default") and access type ("Acc") for each register. Access type definitions used are RW (Read/Write), RO (Read/Only), "—" for reserved / used (essentially the same as RO), and RWC (or just WC) (Read / Write 1's to Clear individual bits). Registers indicated as RW may have some read/only bits that always read back a fixed value (usually 0 if unused); registers designated as RWC or WC may have some read-only or read write bits (see individual register descriptions for details).

Detailed register descriptions are provided in the following section of this document. All offset and default values are shown in hexadecimal unless otherwise indicated

Table 4. VT82C585VPX Registers

Configuration Space VT82C585VPX Header Registers

Offset	PCI Configuration Space Header	Default	Acc
1-0	Vendor ID	1106	RO
3-2	Device ID	0585	RO
5-4	Command	0007	RW
7-6	Status	02A0	WC
8	Revision ID	nn	RO
9	Program Interface	00	RO
Α	Sub Class Code	00	RO
В	Base Class Code	06	RO
C	-reserved- (cache line size)	00	
D	Latency Timer	00	\mathbf{RW}
Е	Header Type	00	RO
F	Built In Self Test (BIST)	00	RO
10-27	-reserved- (base address registers)	00	
28-2F	-reserved- (unassigned)	00	
30-33	-reserved- (expan ROM base addr)	00	
34-3B	-reserved- (unassigned)	00	
3C	-reserved- (interrupt line)	00	
3D	-reserved- (interrupt pin)	00	
3E	-reserved- (minimum grant)	00	
3F	-reserved- (maximum latency)	00	_

Configuration Space VT82C585VPX-Specific Registers

Offset	Cache Control	<u>Default</u>	Acc
50	Cache Control 1	00	RW
51	Cache Control 2	00	RW
52	Non-Cacheable Control	02	RW
53	System Performance Control	00	RW
54	Non-Cacheable Region #1 High Byte	00	RW
55	Non-Cacheable Region #1 Low Byte	00	RW
56	Non-Cacheable Region #2 High Byte	00	RW
57	Non-Cacheable Region #2 Low Byte	00	RW

Offset	DRAM Control	Default	Acc
58	DRAM Configuration 1	40	RW
59	DRAM Configuration 2	05	RW
5A-5F	DRAM Row Ending Address:		
5A	Bank 0 Ending (HA[29:22])	01	RW
5B	Bank 1 Ending (HA[29:22])	01	RW
5C	Bank 2 Ending (HA[29:22])	01	RW
5D	Bank 3 Ending (HA[29:22])	01	RW
5E	Bank 4 Ending (HA[29:22])	01	RW
5F	Bank 5 Ending (HA[29:22])	01	RW
60	DRAM Type	00	RW
61	Shadow RAM Control C0000-CFFFF	00	RW
62	Shadow RAM Control D0000-DFFFF	00	RW
63	Shadow RAM Control E0000-FFFFF	00	RW
64	DRAM Reference Timing	AB	RW
65	DRAM Timing Control 1	00	RW
66	DRAM Timing Control 2	00	RW
67	32-Bit DRAM Width	00	RW
68	-reserved- (do not program)	00	RW
69	-reserved- (do not program)	00	RW
6A	DRAM Refresh Counter	00	RW
6B	DRAM Refresh Control	00	RW
6C	SDRAM Control	00	RW
6D	DRAM Control Drive Strength	00	RW
6E-6F	-reserved-	00	_

Offset	PCI Bus Control	<u>Default</u>	Acc
70	PCI Buffer Control	00	RW
71	CPU to PCI Flow Control 1	00	RW
72	CPU to PCI Flow Control 2	00	WC
73	PCI Master Control 1	00	RW
74	PCI Master Control 2	00	RW
75	PCI Arbitration 1	00	RW
76	PCI Arbitration 2	00	RW
77	-reserved- (chip test - do not program)	00	RW
78-FF	-reserved-	00	—



Configuration Space I/O

Mechanism #1

These ports respond only to double-word accesses. Byte or word accesses will be passed on unchanged.

Port CFB-CF8 - Configuration AddressRW						
31	Configuration Space Enable					
	0 Disableddefault					
	1 Convert configuration data port writes to					
	configuration cycles on the PCI bus					
30-24	Reserved always reads 0					
23-16	PCI Bus Number					
	Used to choose a specific PCI bus in the system					
15-11	Device Number					
	Used to choose a specific device in the system					
10-8	Function Number					
	Used to choose a specific function if the selected					
	device supports multiple functions					
7-2	Register Number					
	Used to select a specific DWORD in the device's					
	configuration space					
1-0	Fixed always reads 0					
	·					

Port CFF-CFC - Configuration DataRW

Refer to PCI Bus Specification Version 2.1 for further details on operation of the above configuration registers.



Register Descriptions

PCI Configuration Space Header

All registers are located in PCI configuration space. They should be programmed using PCI configuration mechanism 1 through CF8 / CFC.

Offset 1	-0 - V	endor IDRO			
15-0					
		evice IDRO			
15-0	ID C	ode (reads 585h to identify the VT82C585VPX)			
Offset 5	5-4 - C	ommandRW			
		rved always reads 0			
9	Fast	Back-to-Back Cycle EnableRW			
	0	Fast back-to-back transactions only allowed to			
		the same agentdefault			
	1	Fast back-to-back transactions allowed to			
		different agents			
8	SERI	R# EnableRW			
	0	SERR# driver disableddefault			
	1	SERR# driver enabled			
		R# is used to report parity errors if bit-6 is set).			
7	Addr	ress / Data SteppingRO			
	0	Device never does steppingdefault			
	1	Device always does stepping			
6		y Error ResponseRW			
	0	Ignore parity errors & continuedefault			
	1	Take normal action on detected parity errors			
5		Palette SnoopRO			
	0	Treat palette accesses normallydefault			
	1	Don't respond to palette accesses on PCI bus			
4		ory Write and Invalidate CommandRO			
	0	Bus masters must use Mem Writedefault			
_	1	Bus masters may generate Mem Write & Inval			
3	-	ial Cycle MonitoringRO			
	0	Does not monitor special cyclesdefault			
•	1	Monitors special cycles			
2		MasterRO Never behaves as a bus master			
	0 1	Can behave as a bus masterdefault			
1	-	ory SpaceRO			
1	0	Does not respond to memory space			
	1	Responds to memory spacedefault			
0	_	pace RO			
U	0	Does not respond to I/O space			
	1	Responds to I/O spacedefault			
	1	responds to 1/0 spaceuclauit			

Offset 7	-6 - Status RW	<u>C</u>
15	Detected Parity Error	
	0 No parity error detected defau	lt
	1 Error detected. May be set even if error	or
	response is disabled (command register bit-6)	
	write one to clea	
14	Signaled System Erroralways reads	0
	1 SERR# asserted	
13	Signaled Master Abortalways reads	0
	1 Transaction aborted by the master	
12	Received Target Abort	
	0 No abort receiveddefau	
	1 Transaction aborted by the target	
	write 1 to clea	
11	Signaled Target Abortalways reads	0
40.0	0 Target Abort never signaled	
10-9	DEVSEL# Timing	
	00 Fast	١.1
	01 Mediumalways reads 0) [
	10 Slow	
0	11 Reserved	Λ
8 7	Data Parity Error Detectedalways reads	
6	Fast Back-to-Back Capablealways reads Reservedalways reads	
5	Reserved always reads 66MHz Capable always reads	
4-0	Reserved always reads	
4-0	Reserveuaiways ieaus	U
Offset 8	s - Revision IDRe	<u>0</u>
0-7	VT82C585VPX Chip Revision Code (00=Fir	
	Silicon)	
0.00		_
	- Programming InterfaceR	
	gister is defined in different ways for each Base/Sul	b-
Class C	ode value and is undefined for this type of device.	
0-7	Interface Identifieralways reads 0	00
Offset A	A - Sub Class CodeRo	O
	Sub Class Codereads 00 to indicate Host Bridge	
0-7	Sub Class Codeleads oo to indicate Host Bridg	30
Offset I	3 - Base Class CodeRe	0
0-7	Base Class Code reads 06 to indicate Bridge Device	
	•	
) - Latency TimerRV	
	s the latency timer value in PCI bus clocks. Bits 0-	-2
are fixed	l, resulting in a granularity of 8 clocks.	
7-3	Guaranteed Time Slice for CPUdefault=	0=
2-0	Reservedalways reads	
	•	
Offset I	E - Header TypeRe	
0-7	Header Type Codereads 00: single function	n
Offset I	F - Built In Self Test (BIST)Re	<u>o</u>
7	BIST Supported reads 0: no supported function	ıs
6	Start Test write 1 to start but writes ignore	ea

3-0 Response Code..........0 = test completed successfully



VT82C585VPX-Specific Configuration Registers

Cache Control

Offset 50- Cache Control 1RW					
7-6	7-6 Cache Enable				
	00 Cache disabledefault				
	01	Cache Init - always does L2 fill			
	10	Cache enable (normal operation)			
	11	-reserved- (do not program)			
5	Linea	ar Burst Enable			
	0	Disabledefault			
	1	Enable			
4-3	Tag (Configuration			
	00	8+0 - 8 Tag bits, no alt (dirty) bitdefault			
	01	7+1 - 7 Tag bits + alternate (dirty) bit			
	10	10 - 10 Tag bits, no alt (dirty) bit			
	11	9+1 - 9 Tag bits + alternate (dirty) bit			
2	SDR	AM Interface Select			
	Selec	ts the function of pins 90-93 and 73-76:			
	0	CWE[0-7]#default			
	1	GWE#, BWE#, SCASx#, SRASx#, SWEx#			
1-0	SRA	M Type			
	00	No SRAMdefault			
	01	Reserved			
	10	Burst SRAM			
	11	Pipeline Burst SRAM			

Offset 51 - Cache Control 2RW				
7-6	Reserved RW, default=0			
5	Backoff CPU			
	Used when register 52h bit-2 is set for "L2 fill when			
	CACHE# is inactive". This bit should normally be			
	set to 0 for best performance, but performance			
	differences are typically not significantly noticable at			
	a system level.			
	0 Defer ready return until L2 is filled default			
	1 Backoff CPU until L2 is filled			
4	Reserved RW, default=0			
3	SRAM Banks			
	0 1 Bankdefault			
	1 2 Banks			
2	Reserved RW, default=0			
1-0	Cache Size			
	00 256Kdefault			
	01 512K			
	10 1M			
	11 2M			



Offset	52 - Non-Cacheable ControlRW	Offset	54 - Non-Cacheable Region #1 High ByteRW
7	C0000-C7FFF Cacheable & Write-Protect def=0	15-8	Base Address MSBs - A<28:21>default=0
6	D0000-DFFFF Cacheable & Write-Protect def=0		As noted below, the base address must be a multiple
5	E0000-EFFFF Cacheable & Write-Protect def=0		of the region size.
4	F0000-FFFFF Cacheable & Write-Protect def=0		
3	Reserved (no function)RW, default=0	<u>Offset</u>	55 - Non-Cacheable Region #1 Low Byte RW
2	L2 Fill	7-3	
	0 Normal L2 cache filldefault		As noted below, the base address must be a multiple
	1 Force the requested data to be filled into the		of the region size.
	L2 cache (provided that L2 cache is enabled),	2-0	Range (Region Size)
	even if the CPU does a read cycle with		000 Disabledefault
	CACHE# de-asserted. Setting this bit		001 64K
	significantly improves performance.		010 128K (Base Address A16 must be 0)
1	Reserved (no function)RW, default=0		011 256K (Base Address A16-17 must be 0)
0	L2 Write Thru/Write-Back		100 512K (Base Address A16-18 must be 0)
	0 Write-Backdefault		101 1M (Base Address A16-19 must be 0)
	1 Write-Thru		110 2M (Base Address A16-20 must be 0)
0.00	5 2 G . D . A . G . J . DW		111 4M (Base Address A16-21 must be 0)
	53 - System Performance ControlRW	Offcot	56 - Non-Cacheable Region #2 High ByteRW
7	Read Around Write		
	0 Disabledefault	15-8	Base Address MSBs - A<28:21>default=0
	1 Enable		As noted below, the base address must be a multiple
6	Cache Read Pipeline Cycle		of the region size.
	0 Disabledefault	Offset	57 - Non-Cacheable Region #2 Low ByteRW
_	1 Enable	7-3	Base Address LSBs - A<20:16>default=0
5	Cache Write Pipeline Cycle	1-3	As noted below, the base address must be a multiple
	0 Disabledefault		of the region size.
	1 Enable	2-0	Range (Region Size)
4	DRAM Pipeline Cycle 0 Disabledefault	20	000 Disable
	0 Disabledefault 1 Enable		001 64K
•			010 128K (Base Address A16 must be 0)
3	PCI Master Peer Concurrency		011 256K (Base Address A16-17 must be 0)
	0 Disabledefault 1 Enable		100 512K (Base Address A16-18 must be 0)
2.0	ReservedRW, default=0		101 1M (Base Address A16-19 must be 0)
2-0	Neserveu Kw, derault=0		110 2M (Base Address A16-20 must be 0)
			111 4M (Base Address A16-21 must be 0)
			(



DRAM Control

These registers are normally set at system initialization time and not accessed after that during normal system operation. Some of these registers, however, may need to be programmed using specific sequences during power-up initialization to properly detect the type and size of installed memory (refer to the VIA Technologies 82C580 BIOS porting guide for details).

Table 5. System Memory Map

Space	Start	Size	Address Range	Comment		
DOS	0	640K	00000000-0009FFFF	Cacheable		
VGA	640K	128K	000A0000-000BFFFF	Used for SMM		
BIOS	768K	16K	K 000C0000-000C3FFF Shadow Ctrl 1			
BIOS	784K	16K	000C4000-000C7FFF	Shadow Ctrl 1		
BIOS	800K	16K	000C8000-000CBFFF	Shadow Ctrl 1		
BIOS	816K	16K	000CC000-000CFFFF	Shadow Ctrl 1		
BIOS	832K	16K	000D0000-000D3FFF	Shadow Ctrl 2		
BIOS	848K	16K	000D4000-000D7FFF	Shadow Ctrl 2		
BIOS	864K	16K	000D8000-000DBFFF	Shadow Ctrl 2		
BIOS	880K	16K	000DC000-000DFFFF	Shadow Ctrl 2		
BIOS	896K	64K	000E0000-000EFFFF	Shadow Ctrl 3		
BIOS	960K	64K	000F0000-000FFFFF	Shadow Ctrl 3		
Sys	1MB	_	00100000-DRAM Top	Can have hole		
Bus	D Top	C 177	DRAM Top-FFFEFFF	0000		
Init 4	4G-64K	64K	FFFEFFFF-FFFFFFF	000Fxxxx alias		
Offset			Configuration 1			
7-5			A Map Type (EDO/FPO	\mathbf{G})		
			Column Address			
			Column Address			
	010 10-bit Column Addressdefault					
	011 11-bit Column Address					
		12-bit Column Address				
			Reserved			
		Reser				
			(A Map Type (SDRAM) oit SDRAM			
			oit SDRAM	ueraun		
4	Resei			RW. default=0		
-				,		
3-1			A Map Type (EDO/FPC			
			Column Address	default		
		,	Column Address			
			t Column Address			
			t Column Address			
			t Column Address			
		Reser				
		Reser				
			A Map Type (SDRAM)			
			oit SDRAM	default		
			oit SDRAM	DW 1 C 1 C		
0	Resei	rved		kw, default=0		

Offset :	59 - DRAM Configuration 2RW		
7-5	Bank 4/5 MA Map Type (EDO/FPG)		
	000 8-bit Column Address		
	001 9-bit Column Address		
	010 10-bit Column Address		
	011 11-bit Column Address		
	100 12-bit Column Address		
	101 Reserved		
	11x Reserved		
	Bank 4/5 MA Map Type (SDRAM)		
	0xx 16Mbit SDRAMdefault		
	1xx 64Mbit SDRAM		
4.2			
4-3	ReservedRW, default=0		
2-0			
	000 Bank 0		
	001 Bank 1		
	010 Bank 2		
	011 Bank 3		
	100 Bank 4		
	101 Bank 5default		
	11x Reserved		
Off4	SA SE DRAMD E- P Address		
	5A-5F - DRAM Row Ending Address:		
All of the	he registers in this group default to 01h:		
Offset	5A - Bank 0 Ending (HA[29:22])RW		
Offee	4.5D Doub 1.5m din c (HA (20.221) DW		
<u>Offse</u>	t 5B - Bank 1 Ending (HA[29:22])RW		
Offse	t 5C - Bank 2 Ending (HA[29:22])RW		
Onset 5C - Dank 2 Enumy (HA[29;22])			
Offse	t 5D - Bank 3 Ending (HA[29:22])RW		
	-		
Offse	t 5E - Bank 4 Ending (HA[29:22])RW		
O 66	4.50 D 1.5 D W (MATON 201)		
Offse	t 5F - Bank 5 Ending (HA[29:22])RW		
Note:			
	for all banks even if no memory is populated. The		
	endings have to be in incremental order.		
0.00	CO. DDAME		
	60 - DRAM TypeRW		
7-6	Reserved always reads 0		
5-4	DRAM Type for Bank 4/5		
	00 Fast Page Mode DRAM (FPG)default		
	01 EDO DRAM (EDO)		
	10 Reserved		
	11 Synchronous DRAM (SDRAM)		
3-2	DRAM Type for Bank 2/3 default=FPG		
1-0	DRAM Type for Bank 0/1 default=FPG		



Offset 61 - Shadow RAM Control 1RW						
7-6 CC000h-CFFFFh						
	00 Read/write disabledefault					
	01	Write enable				
	10	Read enable				
	11 Read/write enable					
5-4	5-4 C8000h-CBFFFh					
		Read/write disabledefault				
	01	Write enable				
	10	Read enable				
	11	Read/write enable				
3-2		0h-C7FFFh				
		Read/write disabledefault				
	01	Write enable				
	10	Read enable				
	11	Read/write enable				
1-0		0h-C3FFFh				
	00	Read/write disabledefault				
	01	Write enable				
	10	Read enable				
	11	Read/write enable				
Offset	62 - Sh	adow RAM Control 2RW				
7-6	DC00	00h-DFFFFh				
	00	Read/write disabledefault				
	01	Write enable				
	10	Read enable				
	11	Read/write enable				
5-4		0h-DBFFFh				
		Read/write disabledefault				
	01	Write enable				
	10	Read enable				
	11	Read/write enable				
3-2 D4000h-D7FFFh						
3-2	D400	0h-D7FFFh				
3-2	D400	0h-D7FFFh Read/write disabledefault				
3-2	D400 00 01	0h-D7FFFh Read/write disabledefault Write enable				
3-2	D400 00 01 10	0h-D7FFFh Read/write disabledefault Write enable Read enable				
ν-	D400 00 01 10 11	Oh-D7FFFh Read/write disable				
1-0	D400 00 01 10 11 D000	Oh-D7FFFh Read/write disable				
ν-	D400 00 01 10 11 D000 00	Oh-D7FFFh Read/write disable				
ν-	D400 00 01 10 11 D000	Oh-D7FFFh Read/write disable				

	, 10 2 00 00 , 111			
Offset 63 - Shadow RAM Control 3RW				
7-6	E0000h-EFFFFh			
	00 Read/write disabledefault			
	01 Write enable			
	10 Read enable			
	11 Read/write enable			
5-4	F0000h-FFFFFh			
	00 Read/write disabledefault			
	01 Write enable			
	10 Read enable			
	11 Read/write enable			
3-2	Memory Hole			
	00 Nonedefault			
	01 512K-640K			
	10 15M-16M (1M)			
	11 14M-16M (2M)			
1	SMI Redirect to A0000h-BFFFFh			
	0 Disable Redirection default			
	1 Enable Redirection			
0	DRAM A0000h-BFFFFh Access			
	0 Disable read write to A0000-B0000 default			
	1 Enable read write to A0000-B0000 in DRAM			
	Note: A0000-BFFFF is reserved for use by VGA			
	controllers for system access to the VGA frame			
	buffer. Setting this bit directs accesses to Axxxx-			
	Bxxxx to corresponding memory addresses in system			
	DRAM instead of directing those accesses to the PCI			
	bus for VGA frame buffer access.			

11 Read/write enable



Offset 64 - DRAM Reference Timing (FPG Only)RW Defines basic timing for Fast Page (FPG) DRAMs. Timing for			66 - DRAM Timing Control 2 (EDO/SDRAM) RW EDO Test Mode Enable
banks populated with EDO / SDRAM is defined per Rx65-66.			0 Normal Modedefault
-	•		1 EDO Test Mode
7-6	RAS Precharge Time		
	00 2T	6	Reserved always reads 0
	01 3T	5	SDRAM CAS Latencydefault=0
	10 4Tdefault		The definition of this bit is the same as Rx6C bit-3 for
	11 6T		backwards compatibility with Apollo VP
5-4	RAS Pulse Width		(VT82C585VP). The two bits are OR'd: if either bit
	00 3T		is set to one, a latency of 3 is selected; if both bits are
	01 4T		0 a latency of 2 is selected.
	10 5Tdefault	4	Reservedalways reads 0
	11 6T	3	Turbo EDO Mode Enable (recommended setting=0)
2.2			0 -2-2-2 Two-Cycle Burstdef
3-2	CAS Read Pulse Width		1 -1-1-1 One-Cycle Burst (only applicable to
	00 1T		turbo EDO DRAMs)
	01 2T (FPG), 1T (EDO)	2	MD to HD FIFO Control. (recommended setting=0)
	10 3T (FPG), 2T (EDO)default	4	
	11 4T (FPG), 3T (EDO)		0 -1-1-1 to pop the data from the DRAM-to-CPU FIFO to the CPUdefault
1	CAS Write Pulse Width		
	0 1T	_	1 -2-2-2 to pop data from the FIFO to the CPU
	1 2Tdefault	1	SDRAM RAS-Precharge Reduction
0	Column Address to CAS Delay (see also Rx67[7])		(recommended setting=0)
	0 1T		0 Use Rx64[7-6] for RAS-Precharge timedef
	1 2Tdefault		1 Reduce the above by 1T for SDRAM access
		0	SDRAM RAS-to-CAS Delay Reduction
Offset	65 - DRAM Timing Control 1 (EDO/SDRAM)RW		(recommended setting=1)
7-6	Page Mode Control		0 Use Rx64[0] for Column Address to CAS
	00 Page closes after accessdefault		delay for SDRAM)default
	01 Reserved		1 Column Address to CAS delay is fixed at 1T
	10 Page stays open after access		for SDRAM
	11 Page closes if CPU is idle		
5	Fast DRAM Decoding Enable	Offset	67 - 32-Bit DRAM WidthRW
	0 End of Second T2default	7	RAS to Column Address Delay
	1 End of First T2 (recommended setting)		This bit determines the number of CPU clocks from
	· · · · · · · · · · · · · · · · · · ·		RAS assertion to column address assertion.
	Determines the latch point for all DRAM-related		0 1T (recommended setting)default
	decoding (bank, page-hit, MA address mux setup,		1 2T (only set this with heavily loaded DRAM)
	etc). DRAM control signals (RAS#, CAS#, or	6	
	SDRAM commands) are also activated at this point.	U	0 No NA# delay, 3-1-1-1-2-1-1 for L2 cache
4	EDO DRAM Leadoff Cycle Reduction		· · · · · · · · · · · · · · · · · · ·
	0 Normal leadoff cycle (recommended)default		read hit (recommended setting) default
	1 Reduce leadoff cycle by 1T		1 Delay NA# 1T, 3-1-1-1-3-1-1-1
3	DRAM Data Latch Delay .(recommended setting=0)		This bit only applies when 2 banks of PBSRAM is
3	DRAW Data Laten Delay (recommended setting=0)		
3	0 Latch DRAM data 1 cycle before CPU def		installed.
J	0 Latch DRAM data 1 cycle before CPU def	5	Bank 5 Width. 1=32-bit, 0= 64 bitdefault=64
	 0 Latch DRAM data 1 cycle before CPU def 1 Latch DRAM Data ½ cycle before the CPU 	5 4	
2	 0 Latch DRAM data 1 cycle before CPU def 1 Latch DRAM Data ½ cycle before the CPU Pin 88 Function Select 		Bank 5 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 4 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 3 Width. 1=32-bit, 0= 64 bitdefault=64
	0 Latch DRAM data 1 cycle before CPU def 1 Latch DRAM Data ½ cycle before the CPU Pin 88 Function Select 0 DB32	4	Bank 5 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 4 Width. 1=32-bit, 0= 64 bitdefault=64
2	0 Latch DRAM data 1 cycle before CPU def 1 Latch DRAM Data ½ cycle before the CPU Pin 88 Function Select 0 DB32	4 3	Bank 5 Width. 1=32-bit, 0= 64 bit default=64 Bank 4 Width. 1=32-bit, 0= 64 bit default=64 Bank 3 Width. 1=32-bit, 0= 64 bit default=64 Bank 2 Width. 1=32-bit, 0= 64 bit default=64
2	0 Latch DRAM data I cycle before CPU def 1 Latch DRAM Data ½ cycle before the CPU Pin 88 Function Select 0 DB32	4 3 2 1	Bank 5 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 4 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 3 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 2 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 1 Width. 1=32-bit, 0= 64 bitdefault=64
2	0 Latch DRAM data 1 cycle before CPU def 1 Latch DRAM Data ½ cycle before the CPU Pin 88 Function Select 0 DB32	4 3 2	Bank 5 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 4 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 3 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 2 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 1 Width. 1=32-bit, 0= 64 bitdefault=64
2	0 Latch DRAM data 1 cycle before CPU def 1 Latch DRAM Data ½ cycle before the CPU Pin 88 Function Select 0 DB32	4 3 2 1	Bank 5 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 4 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 3 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 2 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 1 Width. 1=32-bit, 0= 64 bitdefault=64
2	0 Latch DRAM data 1 cycle before CPU def 1 Latch DRAM Data ½ cycle before the CPU Pin 88 Function Select 0 DB32	4 3 2 1	Bank 5 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 4 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 3 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 2 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 1 Width. 1=32-bit, 0= 64 bitdefault=64
2	0 Latch DRAM data 1 cycle before CPU def 1 Latch DRAM Data ½ cycle before the CPU Pin 88 Function Select 0 DB32	4 3 2 1	Bank 5 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 4 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 3 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 2 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 1 Width. 1=32-bit, 0= 64 bitdefault=64
2	0 Latch DRAM data 1 cycle before CPU def 1 Latch DRAM Data ½ cycle before the CPU Pin 88 Function Select 0 DB32	4 3 2 1	Bank 5 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 4 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 3 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 2 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 1 Width. 1=32-bit, 0= 64 bitdefault=64
2	0 Latch DRAM data 1 cycle before CPU def 1 Latch DRAM Data ½ cycle before the CPU Pin 88 Function Select 0 DB32	4 3 2 1	Bank 5 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 4 Width. 1=32-bit, 0= 64 bitdefault=64 Bank 3 Width. 1=32-bit, 0= 64 bitdefault=64

not empty (recommended setting).



Offset	68 - Reserved (Do Not Program)RW	Offset	6C - SDRAM ControlRW
7-4	Reserved (do not program)RW, default = 0	7	64Mbit SDRAM Interleave
3	Pin 126 Function Select		0 2-bank interleave for 64Mbit SDRAM default
	0 Pin 126 remains high all the time (for		1 4-bank interleave for 64Mbit SDRAM
	backwards compatibility with VT82C585VP-		Note: This bit is a don't-care for 16Mbit SDRAM
	based designs that drive the VT82C587VP	6	SDRAM Burst Write
	"CMD5" input with pin 126)default		0 Disableddefault
	1 Pin 126 is MA12 for 64Mb DRAM support		1 Enabled
2-0	Reserved (do not program)RW, default = 0	5	SDRAM Bank Interleave Enable
			0 Disabled (bit-7 is a don't care) default
<u>Offset</u>	69 - Reserved (Do Not Program)RW		1 Enabled
7-0	Reserved (do not program)RW, default = 0		16Mbit is 2-way only
			64Mbit is defined by bit-7 of this register
		4	Reserved RW, default= 0
		3	SDRAM CAS Latency (see also Rx66[5])
			0 Cycle latency is 2 (RX66[5] must be 0). default
Offset	6A - Refresh CounterRW		1 Cycle latency is 3
7-0	Refresh Counter (in units of 16 CPUCLKs) def=0	2-0	SDRAM Operation Mode Select
7-0	note: When set to 00, DRAM refresh is disabled		000 Normal SDRAM Modedefault
	note. When set to oo, DRAW terresh is disabled		001 NOP Command Enable
Offset	6B - Refresh ControlRW		010 All-Banks-Precharge Command Enable.
7	CBR (CAS-before-RAS) Refresh		CPU-to-DRAM cycles are converted
,	0 Disable CBR Refreshdefault		to All-Banks-Precharge commands.
	1 Enable CBR Refresh		011 CPU-to-DRAM cycles are converted to
6	Burst Refresh (Burst 4 Times)		commands and the commands are driven on
Ū	0 Disable burst refreshdefault		MA[11:0]. The BIOS selects an appropriate
	1 Enable burst refresh		host address for each row of memory such that
5-3	Reserved RW, default=0		the right commands are generated on
2	Extended Timing		MA[11:0].
_	0 Normal Timingdefault		100 CBR Cycle Enable
	1 Force 2T from MA to RAS# and CAS# falling		101 Reserved
	for all cases (use this setting for heavily loaded		11x Reserved
	DRAM and direct drive)	Offcot	6D - DRAM Control Drive StrengthRW
1-0	Reservedalways read 0		
	·	7	Bank Decoding Testdefault=0
		6	MA[0:1] Drive
			0 12mAdefault
		_	1 24mA
		5	Duplicate Copy of MA[0:1]
			Pin N17 Pin M17 Drive Control
			0 RAS5# RAS4# bit 0 default
			1 MA1 MA0 bit 6
		4	Force SMM Mode default=0
		3	SDRAM Command Drive (SRAS#, SCAS#, SWE#)
			0 12mAdefault
		_	1 24mA
		2	MA[2:13] / WE# Drive
			0 12mAdefault
		_	1 24mA
		1	CAS# Drive
			0 8 mAdefault
			1 12 mA

RAS# Drive

1 24mA

0 12mAdefault



PCI Bus Control

These registers are normally programmed once at system initialization time.

mitanza	mon n	me.
Offset 7	0 - PC	CI Buffer ControlRW
7	CPU	to PCI Post-Write
	0	Disableddefault
	1	Enabled
6	PCI I	Master to DRAM Post-Write
	0	Disableddefault
	1	Enabled
5	PCI I	Master to DRAM Prefetch
	0	Disableddefault
	1	Enabled
4	Rese	rvedRW, default= 0
3-2		rved always reads 0
1		Retry for CPU QW Access
-	0	Disableddefault
	1	Enabled
0	PCLI	Master Does Not Flush CPU to PCI Buffer
v	0	Master flushes CPU-to-PCI bufferdefault
	1	Master does not flush CPU to PCI buffer
	•	Master does not ridsh or o to rer surrer
Offset 7	1 - CI	PU to PCI Flow Control 1RW
7	Dyna	mic Burst
	0	Disableddefault
	1	Enabled (see note under bit-3 below)
6	Byte	Merge
	0	S
	1	Enabled
5	Reser	
4	PCI I	I/O Cycle Post Write
	0	Disableddefault
	1	Enabled
3	PCI I	Burst
	0	Disableddefault
	1	Enabled (bit7=1 will override this option)
bit-7	bit-3	<u>Operation</u>
0	0	Every write goes into the write buffer and no
		PCI burst operations occur.
0	1	If the write transaction is a burst transaction,
		the information goes into the write buffer and
		burst transfers are later performed on the PCI
		bus. If the transaction is not a burst, PCI write
		occurs immediately (after a write buffer flush).
1	X	Every write transaction goes to the write
		buffer; burstable transactions will then burst
		on the PCI bus and non-burstable won't. This
		is the normal setting.
2	Enah	le PCI Fast Back-to-Back Write def=0 (disa)
1		le Quick Frame Generation def=0 (disabled)
0		le 1 Wait State PCI Cycles def=0 (disabled)
v		(dibuoted)

Offset	72 - CP	U to PCI Flow Control 2RWC
7	Retry	Status over 16 / 64 Times
	0	No retry occurreddefault
	1	Retry occurred write 1 to clear
6	Retry	Timeout Action
	0	Retry Forever (record status only) default
	1	Flush buffer or return FFFFFFF for read
5-4	Retry	Count and Retry Backoff
	00	Retry 2 times, back off CPU default
		Retry 16 times
	10	Retry 4 times, back off CPU
	11	Retry 64 times
3	Clear	Failed Data and Continue Retry
	0	Disabled default
	1	When data is posting and retry fails, pop the
		failed data if any, and keep posting
2		Backoff on PCI Read Retry Failure
	0	Disableddefault
	1	Backoff CPU when reading data from PCI and
		retry fails
1	Reduc	ce 1T for FRAME# Generation
	0	Disableddefault
	1	Enabled
0	Reduc	ce 1T for CPU Read PCI Slave
	0	Disableddefault
	1	Enabled (bypass TRDY# to LRDY#)



Offset	/3 - PC	1 Master Control 1KW
7	Loca	l Memory Decoding
	0	Fast (address phase)default
	1	Slow (first data phase)
6	PCI I	Master 1-Wait-State Write
	0	Zero wait state TRDY# responsedefault
	1	One wait state TRDY# response
5	PCI I	Master 1-Wait-State Read
	0	Zero wait state TRDY# responsedefault
	1	One wait state TRDY# response
4	Rese	
3	Asser	rt STOP# after PCI Master Write Timeout
	0	Disableddefault
	1	Enabled
2	Asser	rt STOP# after PCI Master Read Timeout
	0	Disableddefault
	1	Enabled
1	LOC	K# Function
	0	Disableddefault
	1	Enabled
0	PCI 1	Master Broken Timer Enable
	0	2 154010 0
	1	Enabled. Force into arbitration when there is
		no FRAME# 16 PCICLK's after the GRANT.
Offeed 7	74 DC	CI Master Control 2RW
7		Enhance Command Support
		Disableddefault
	1	Enabled
6		Master Single Write Merge
	-	Disableddefault
= 0	1	Enabled
5-0	Rese	rved always reads 0

Offset	75 - PCI Arbitration 1 RW
7	Arbitration Mechanism
	0 PCI has prioritydefault
	1 Fair arbitration between PCI and CPU
6	Arbitration Mode
	0 REQ-based (arbitrate at end of REQ#) default
	1 Frame-based (arbitrate at end of each
	FRAME#)
5-4	Reserved RW, default=0
3-0	PCI Master Bus Time-Out
	(force into arbitration after a period of time)
	0000 Disable default
	0001 1x32 PCICLKs
	0010 2x32 PCICLKs
	1111 15x32 PCICLKs
ffset	76 - PCI Arbitration 2RW
7	Master Priority Rotation Enable
	0 Disable (arbitration per Rx75 bit-7) default
	1 Enable (arbitration per bits 5-4 of this register)
	(gives the CPU higher priority than either of
	the mechanisms defined by Rx75 bit-7)
6	Reservedalways reads 0
5-4	Master Priority Rotation Control
	00 Disabled (arbitration per Rx75 bit-7) default
	01 Grant to CPU after every PCI master grant
	10 Grant to CPU after every 2 PCI master grants
	11 Grant to CPU after every 3 PCI master grants
	With setting 01, the CPU will always be granted
	access after the current bus master completes, no
	matter how many PCI masters are requesting. With
	setting 10, if other PCI masters are requesting during
	the current PCI master grant, the highest priority
	master will get the bus after the current master
	completes, but the CPU will be guaranteed to get the
	bus after that master completes. With setting 11, if
	other PCI masters are requesting, the highest priority
	will get the bus next, then the next highest priority
	will get the bus, then the CPU will get the bus. In
	other words, with the above settings, even if multiple
	PCI masters are continuously requesting the bus, the
	CPU is guaranteed to get access after every master
	grant (01), after every other master grant (10) or after
	every third master grant (11).

3-1 Reserved

Reserved

.....always reads 0

.....RW, default=0



ELECTRICAL SPECIFICATIONS

Absolute Maximum Ratings

Parameter	Min	Max	Unit
Ambient operating temperature	0	70	oC.
Storage temperature	-55	125	oC.
Input voltage	-0.5	5.5	Volts
Output voltage ($V_{DD} = 3.1 - 3.6V$)	-0.5	$V_{DD} + 0.5$	Volts

Note: Stress above the conditions listed may cause permanent damage to the device. Functional operation of this device should be restricted to the conditions described under operating conditions.

DC Characteristics

 $TA-0-70^{O}C$, $V_{DD}=5V+/-5\%$, GND=0V

Symbol	Parameter	Min	Max	Unit	Condition
V_{IL}	Input low voltage	-0.50	0.8	V	
V _{IH}	Input high voltage	2.0	V _{DD} +0.5	V	
V_{OL}	Output low voltage	-	0.45	V	I _{OL} =4.0mA
V _{OH}	Output high voltage	2.4	-	V	I _{OH} =-1.0mA
$I_{\Pi\!L}$	Input leakage current	-	+/-10	uA	$0 < V_{IN} < V_{DD}$
I_{OZ}	Tristate leakage current	-	+/-20	uA	$0.45 < V_{OUT} < V_{DD}$
I_{CC}	Power supply current	-		mA	



AC Timing Specifications

AC timing specifications provided are based on external zero-pf capacitance load. Min/max cases are based on the following table:

Table 6. AC Timing Min / Max Conditions

	Min	Max
VDD-CPU, VDD-PCI, VDD-DRAM	5.25	3.135
VDD	5.25	4.75
Temperature	0	70

Pad load derating curve specifications are listed from 0pf to 80pf with 5pf resolution; above 80 pf use 20 pf resolution up to 200 pf. The following pads are provided:

Table 7. PAD Load Derating Curve (I/V curve)

External pad name	Voltage	Remark
vpad000	3.3	
vpad 001	3.3	
vpad 002	3.3	
vpad 005	3.3	24mA
vpad 007	3.3	12mA
vpad 009	3.3	12mA
vpad 011	3.3	8mA
vpad 012	3.3	
vpad 013	3.3	
vpad 014	3.3	



Table 8. AC Characteristics - CPU Cycle Timing

Parameter	Min	Max	Pad	Notes
ADS# Setup Time to CCLK Rising	5			
WR# Setup Time to CCLK Rising	5			
MIO# Setup Time to CCLK Rising	5			
DC# Setup Time to CCLK Rising	5			
BE[7:9[# Setup Time to CCLK Rising	5			
HITM# Setup Time to CCLK Rising	5			
CACHE# Setup Time to CCLK Rising	5			
HA[31:3] Setup Time to CCLK Rising	5			
ADS#,HITM#,WR#,MIO#,DC#,BE[7:0]#,CACHE# Hold Time from CCLK Rising	2			
HA[31:3] Hold Time from CCLK Rising	2			
BRDY# Valid Delay From CCLK Rising	3	8	vpad000	0 pf
NA# Valid Delay From CCLK Rising	3	7	vpad000	0 pf
AHOLD Valid Delay From CCLK Rising	3	7	vpad000	0 pf
BOFF# Valid Delay From CCLK Rising	3	7	vpad000	0 pf
EADS# Valid Delay From CCLK Rising	3	7	vpad000	0 pf
KEN#/INV# Valid Delay from CCLK Rising	3	7	vpad000	0 pf
BE[7:0]# Valid Delay from CCLK Rising	4	9	vpad002	0 pf
HA[31:3] Valid Delay from CCLK Rising	4	13	vpad002	0 pf
HA[31:3] Float Delay from CCLK Rising	4	9		0 pf



Table 9. AC Characteristics - L2 Cache Timing

Parameter	Min	Max	Pad	Notes
COE# Valid Delay from CCLK Rising	2	6	vpad000	0 pf
TA[9:0] Valid Delay from CCLK Rising	3	9	vpad001	0 pf
TA[9:0] setup time to CCLK Rising	8			
TA[9:0] Hold Time from CCLK Rising	1			
TAGWE# Valid Delay from CCLK Rising	2	6	vpad000	0 pf
CWE[7:0]#/GWE#/BWE# Active Delay from CCLK Rising	2	6	vpad000	0 pf
CCS#(CALE) Valid Delay from CCLK Rising	2	6	vpad000	0 pf
CADS# Valid Delay from CCLK Rising	2	6	vpad000	0 pf
CADV# Valid Delay from CCLK Rising	2	6	vpad000	0 pf

Table 10. AC Characteristics - DRAM Interface Timing

Parameter	Min	Max	Pad	Notes
RAS[5:0] Valid Delay from CCLK Rising	4	9	vpad005	0 pf
CAS[7:0]# Valid Delay from CCLK Rising (EDO)	3	8	vpad007	0 pf
DQM[7:0]# Valid Delay from CCLK Rising (SDRAM)	3	7	vpad011	
SRAS# Valid Delay from CCLK Rising	3	7	vpad005	
SCAS# Valid Delay from CCLK Rising	3	7	vpad005	
SWE#,SWEB# Valid Delay from CCLK Rising	3	7	vpad005	
MA[11:2]# Valid Delay from CCLK Rising on first Clock after RAS# asserts	4	9	vpad005	startpage 0 pf
MA[1:0] Valid Delay from CCLK Rising (burst)	4	10	vpad005	0 pf
MA[11:0] Flow Through Delay from HA for first read cycle	4	10	vpad005	Leadoff, 0pf
MWE# Valid Delay from CCLK Rising	6	15	vpad005	0 pf



Table 11. AC Characteristics - PCI Cycle Timing

Parameter	Min	Max	Pad	Notes
AD[31:0] Valid Delay from PCLK Rising (address phase)	5	12	vpad012	0 pf
AD[31:0] Valid Delay from PCLK Rising (data phase)	5	11		
AD[31:0] Setup Time to PCLK	7			
AD[31:0] Hold Time	2			
CBE[3:0]#,FRAME#,TRDY#,IRDY#,STOP#,DEVSEL# Valid Delay from PCLK Rising	3	8	vpad013	0 pf
CBE[3:0]#,FRAME#,TRDY#,IRDY#,STOP#,DEVSEL# Float Delay from CCLK Rising		10		
CBE[3:0]#,FRAME#,TRDY#,IRDY#,STOP#,DEVSEL# Setup Time to CCLK Rising	7			
CBE[3:0]#,FRAME#,TRDY#,IRDY#,STOP#,DEVSEL# Hold Time from CCLK Rising	2			
PHLD#,REQ[3:0]# Setup Time to PCLK Rising	7			
GNT[3:0]#,PGNT# Valid Delay from PCLK Rising	2	6		

Table 12. AC Characteristics - Data Timing

Parameter	Min	Max	Fig.	Notes
HD Valid Delay from CCLK Rising	3	7	vpad001	0 pf
HD Setup Time to CCLK Rising	2			
HD Hold Time from CCLK Rising	2			
MD Valid Delay from CCLK Rising (SDRAM)	3	8	vpad001	0 pf
MD Valid Delay from CCLK Falling (EDO/FP)	4	14		
MD Setup Time to CCLK Rising (SDRAM)	2			
MD Setup Time to CCLK Falling (EDO)	2			
MD Hold Time from CCLK Rising (SDRAM)	3			
MD Hold Time from CCLK Falling (EDO)	3			

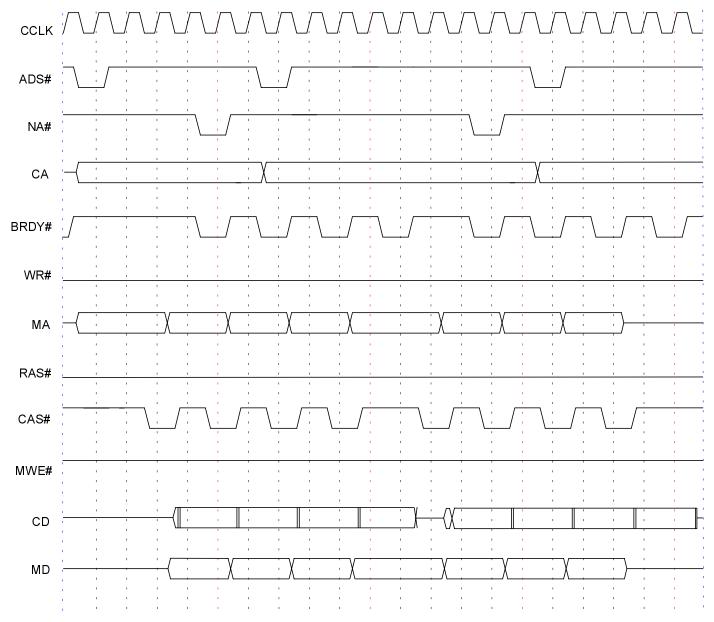


Figure 6. DRAM READ PIPE LINE EDO 5-2-2-2, 3-2-2-2

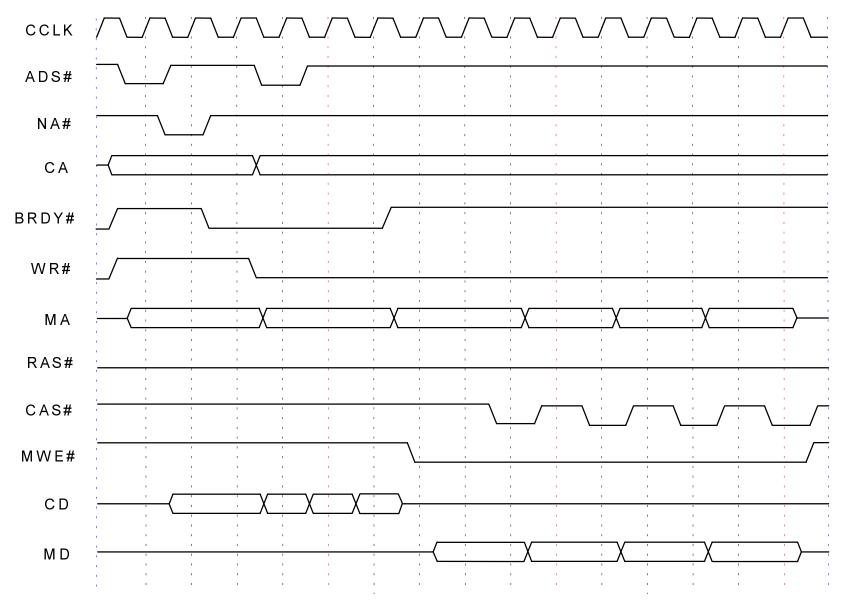


Figure 7. POST WRITE 3111,DRAM EDO 2222

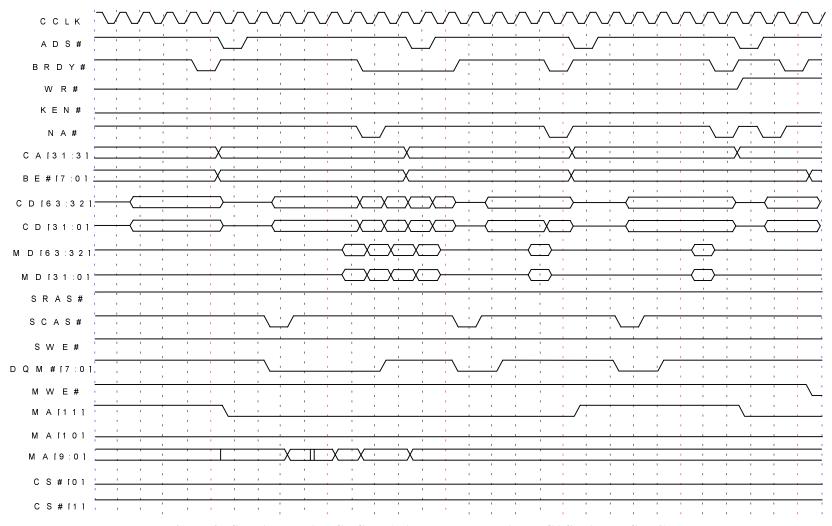


Figure 8. SDRAM READ CYCLE (BANK INTERLEAVE, CAS LATENCY=3)

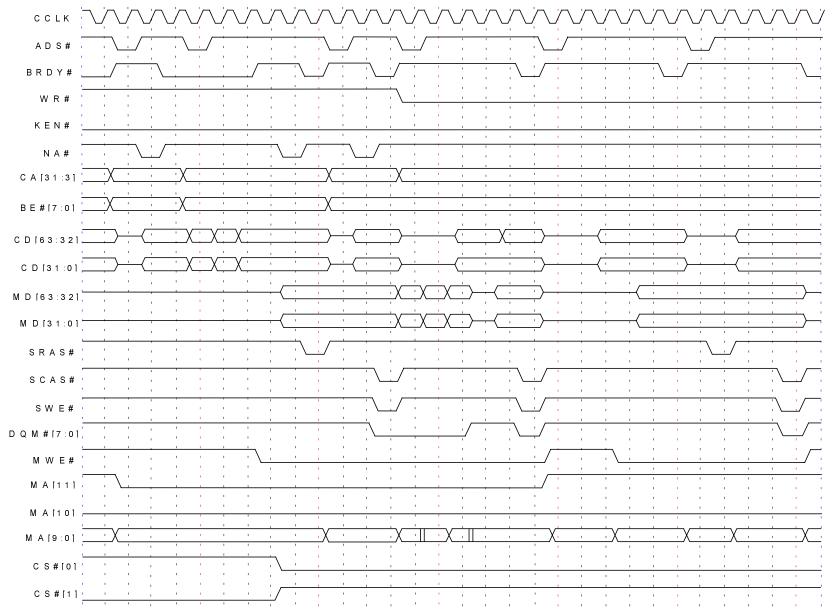


Figure 9. SDRAM WRITE CYCLE (BANK INTERLEAVE)

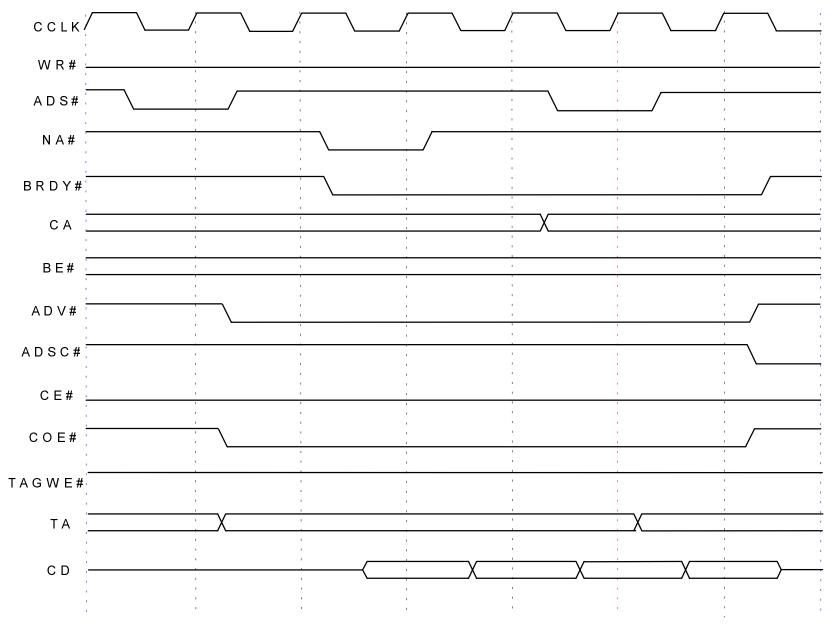


Figure 10. CPU READ HIT SYNCHRONOUS SRAM 3111

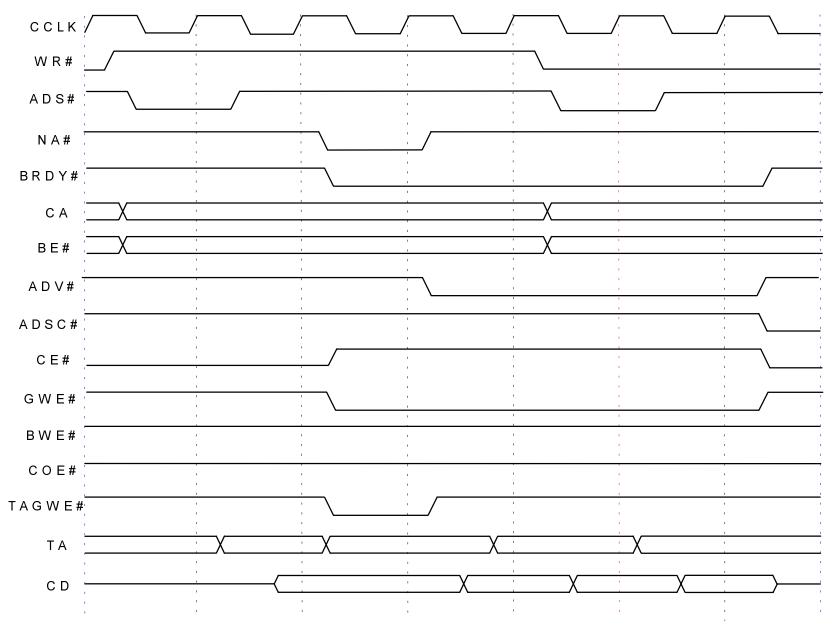


Figure 11. CPU WRITE HIT SYNCHRONOUS SRAM 3111

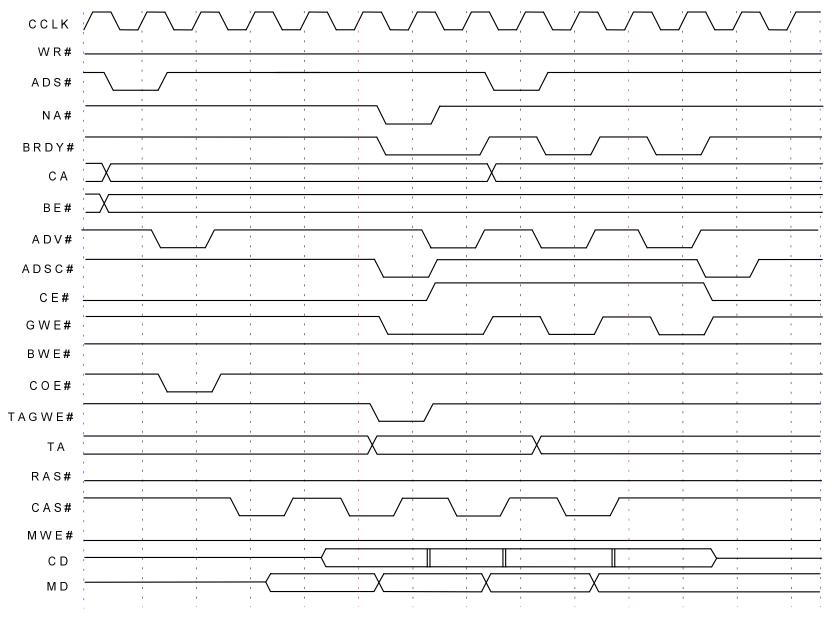


Figure 12. CPU READ MISS FILL SYNCHRONOUS SRAM

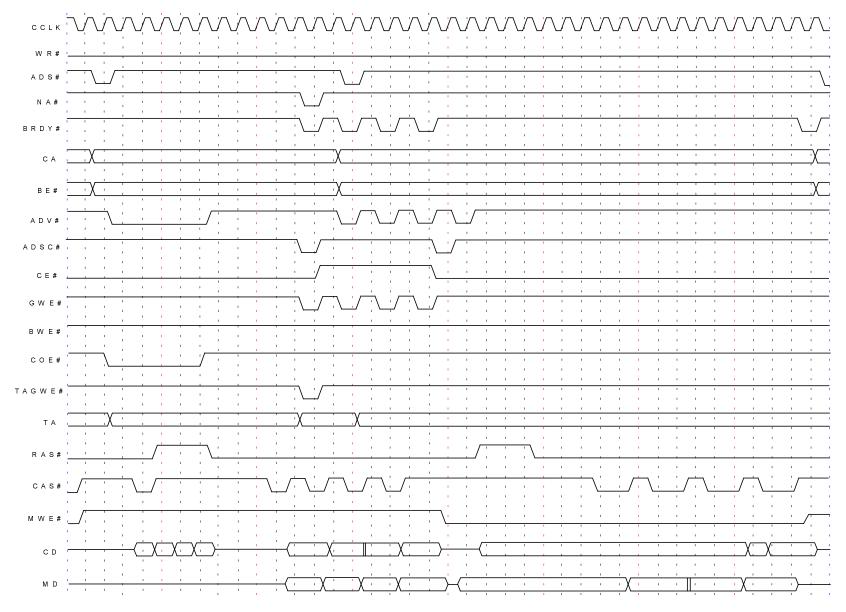


Figure 13. CPU READ MISS DIRTY L2 WRITE BACK FILL

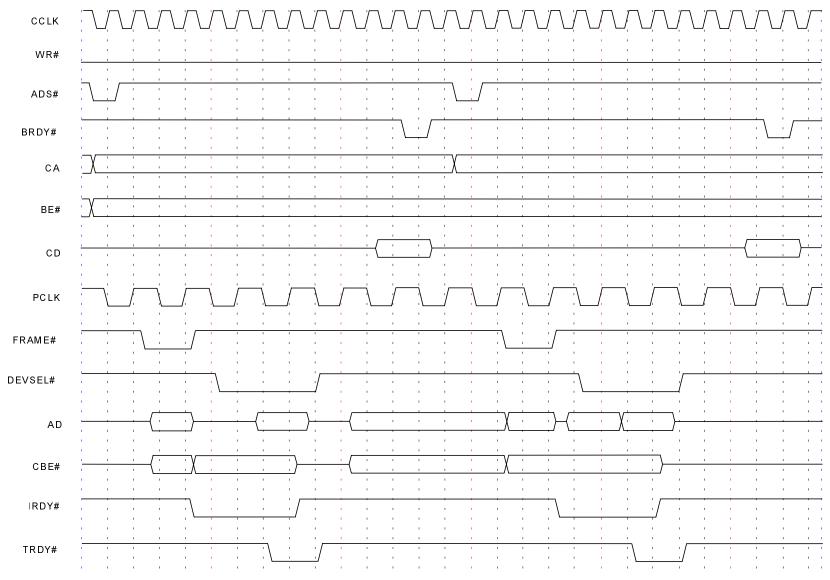


Figure 14. CPU READ PCI SLAVE

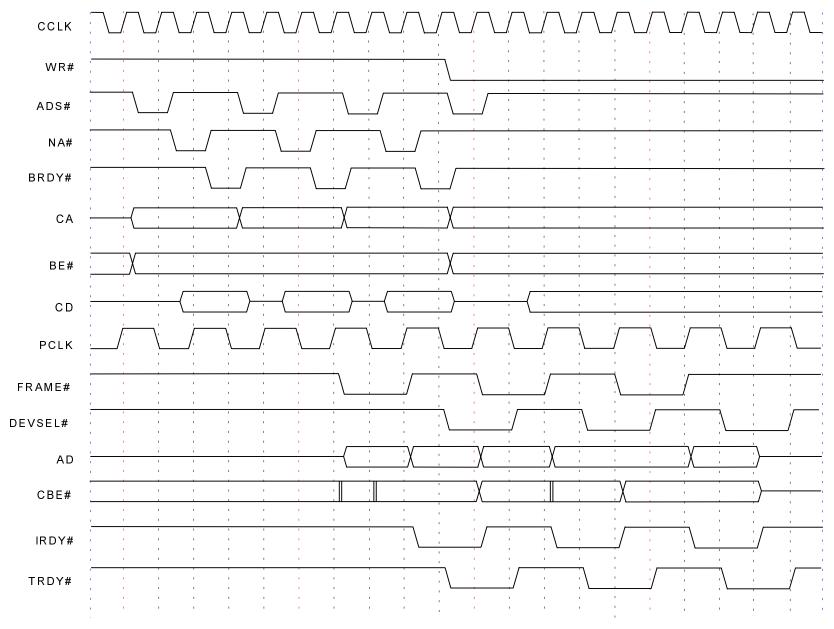


Figure 15. CPU WRITE PCI SLAVE WRITE BUFFER ON FAST BACK TO BACK

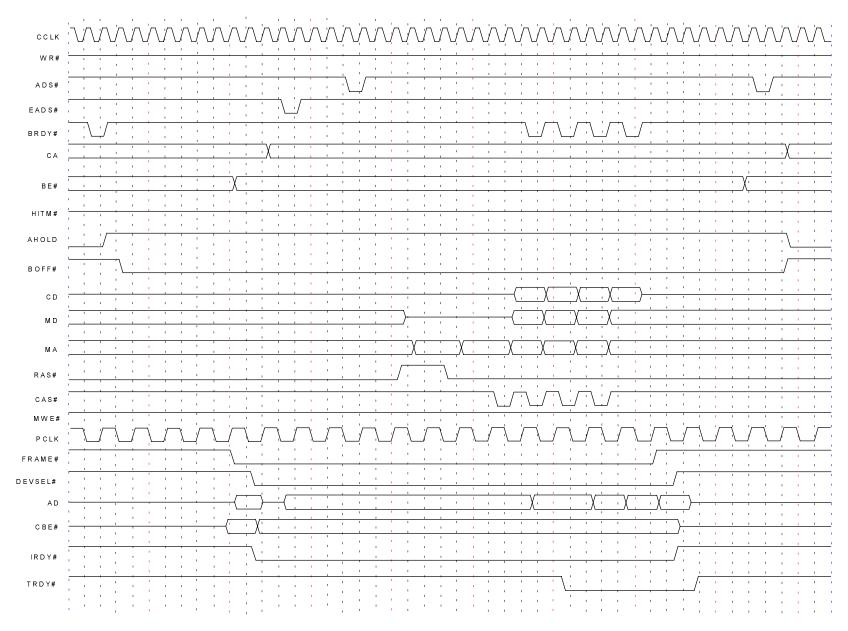


Figure 16. PCI MASTER READ HIT DRAM

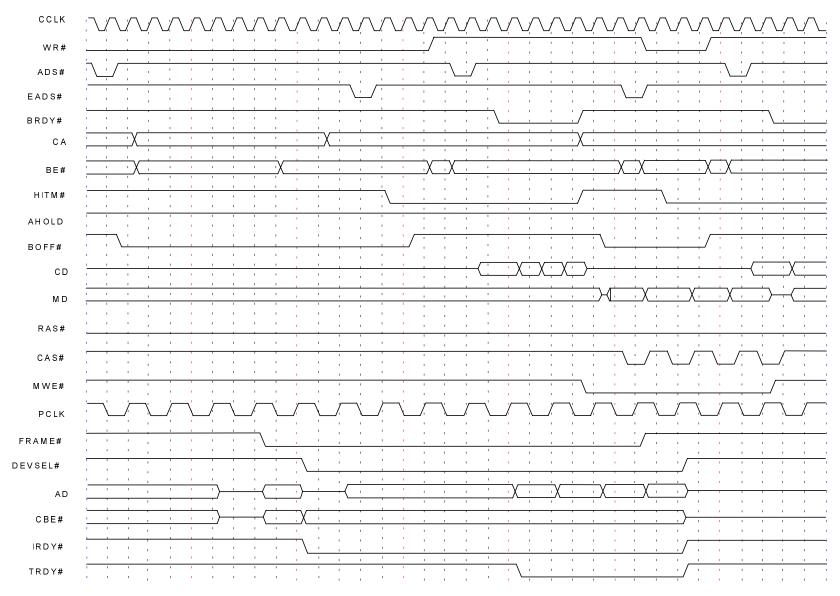


Figure 17. PCI MASTER READ L1 SNOOP TO DRAM

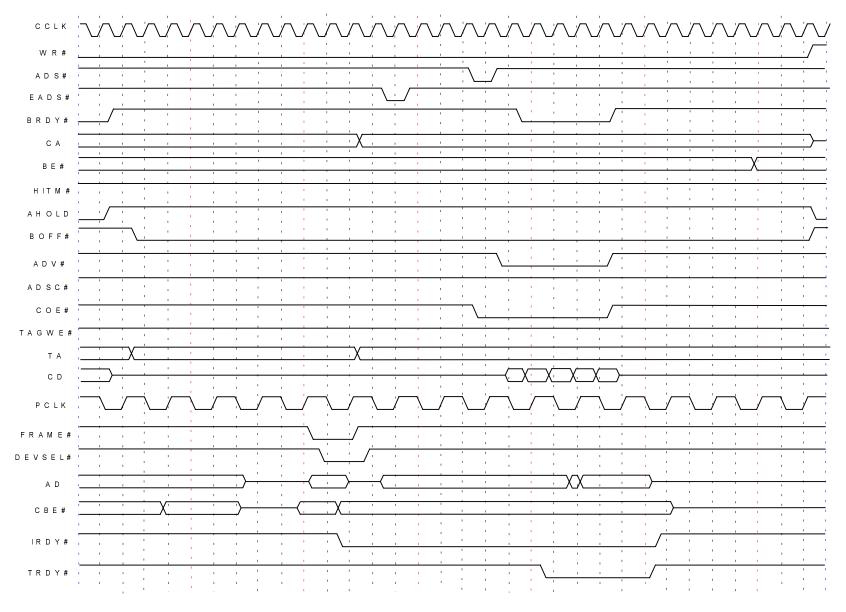


Figure 18. PCI MASTER READ HIT L2

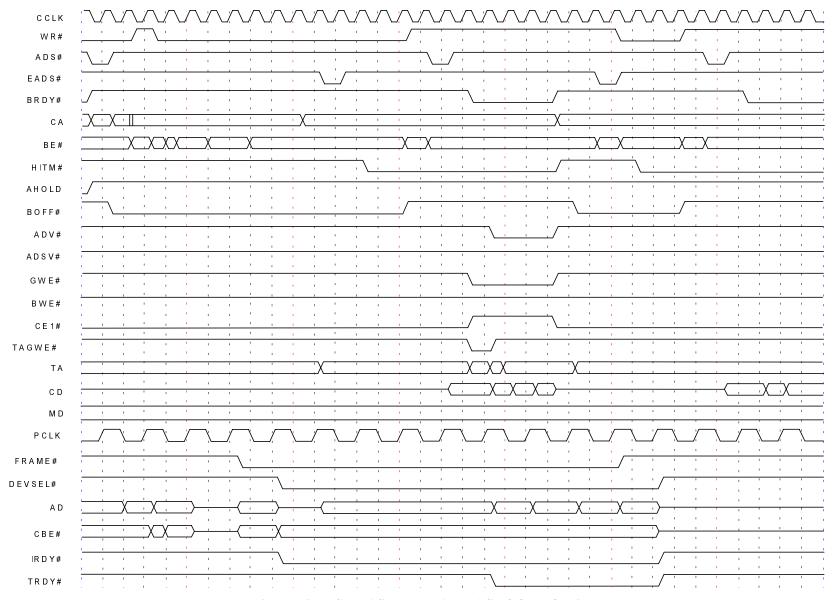


Figure 19. PCI MASTER READ L1 SNOOP TO L2 $\,$

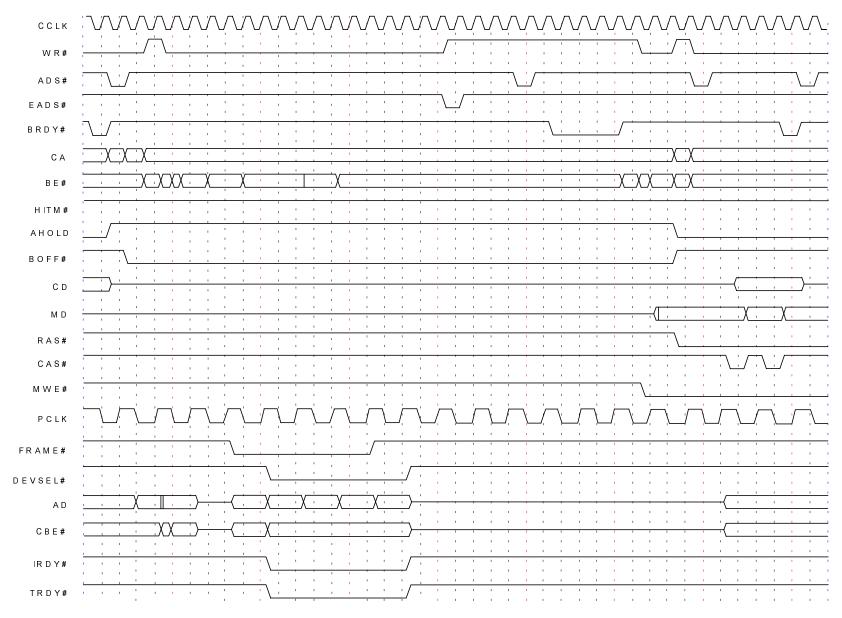


Figure 20. PCI MASTER WRITE DRAM

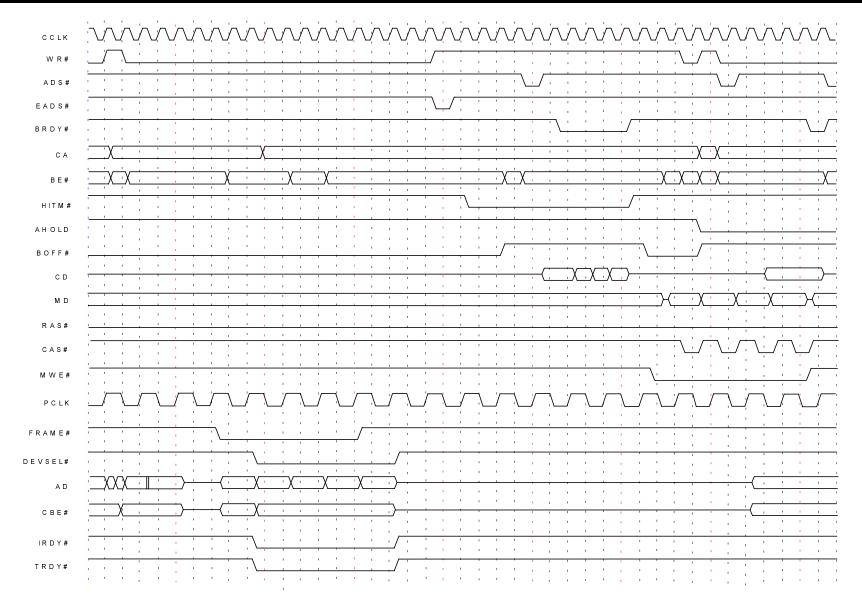


Figure 21. PCI MASTER WRITE HIT L1 SNOOP TO DRAM

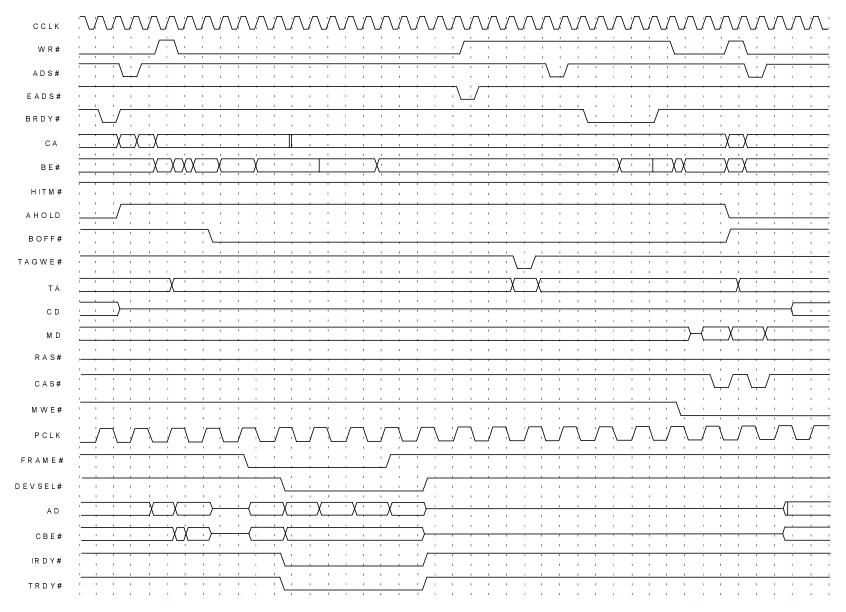


Figure 22. PCI MASTER WRITE HIT L2

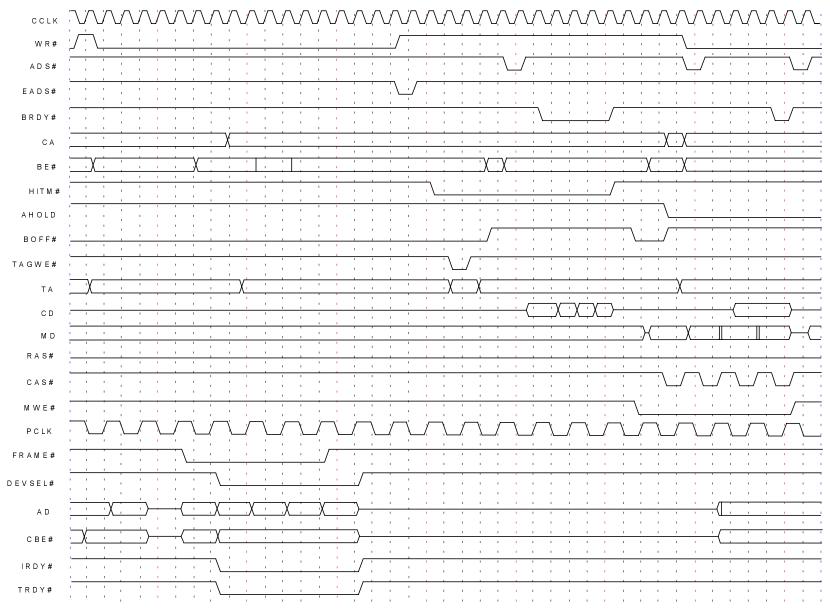


Figure 23. PCI MASTER WRITE HIT L2, L1 HITM

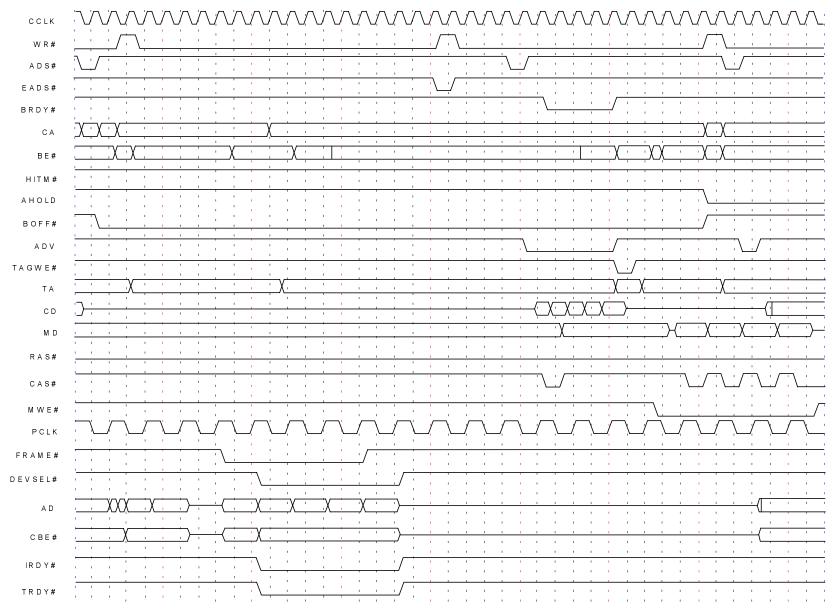


Figure 24. PCI MASTER WRITE HIT L2 & DIRTY

PACKAGE MECHANICAL SPECIFICATIONS

PQFP-208

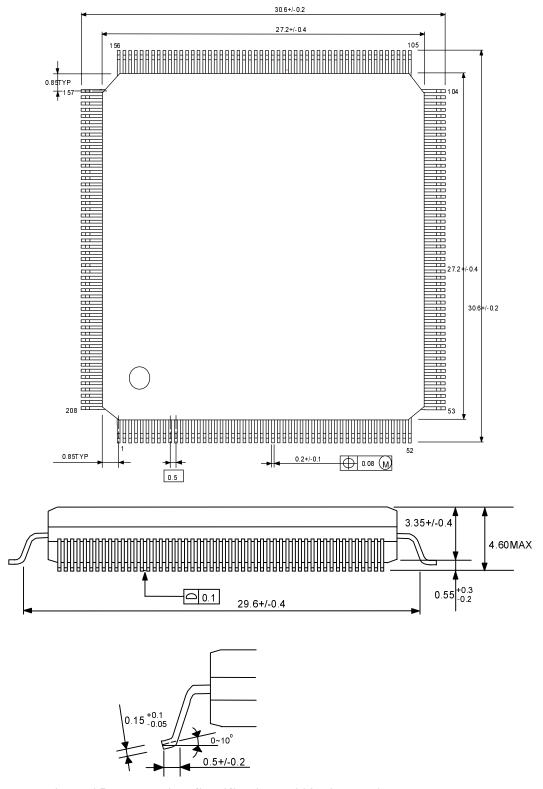


Figure 25. Mechanical Specifications - 208-Pin Plastic Flat Package

PQFP-100

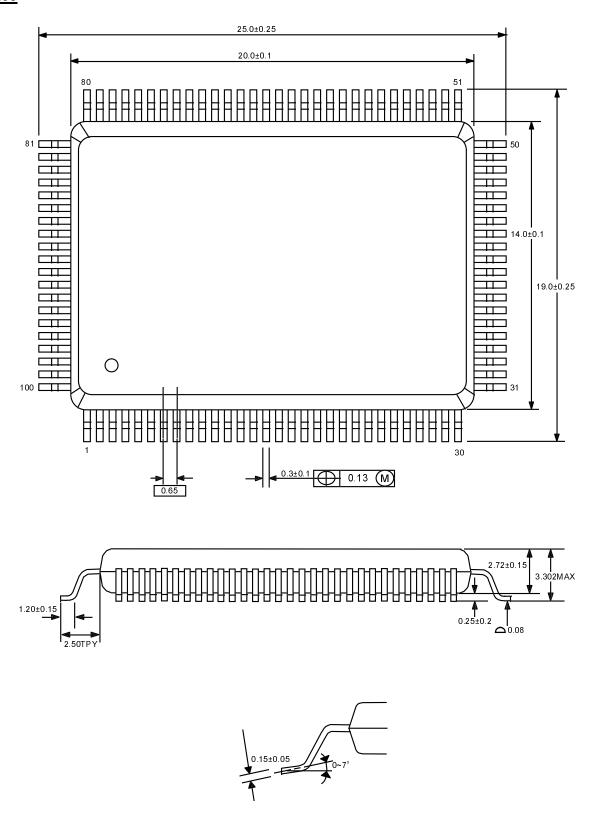


Figure 26. Mechanical Specifications - 100-Pin Plastic Flat Package